

Mutiscale Models of Materials: Linking Microstructure and Macroscopic Behavior

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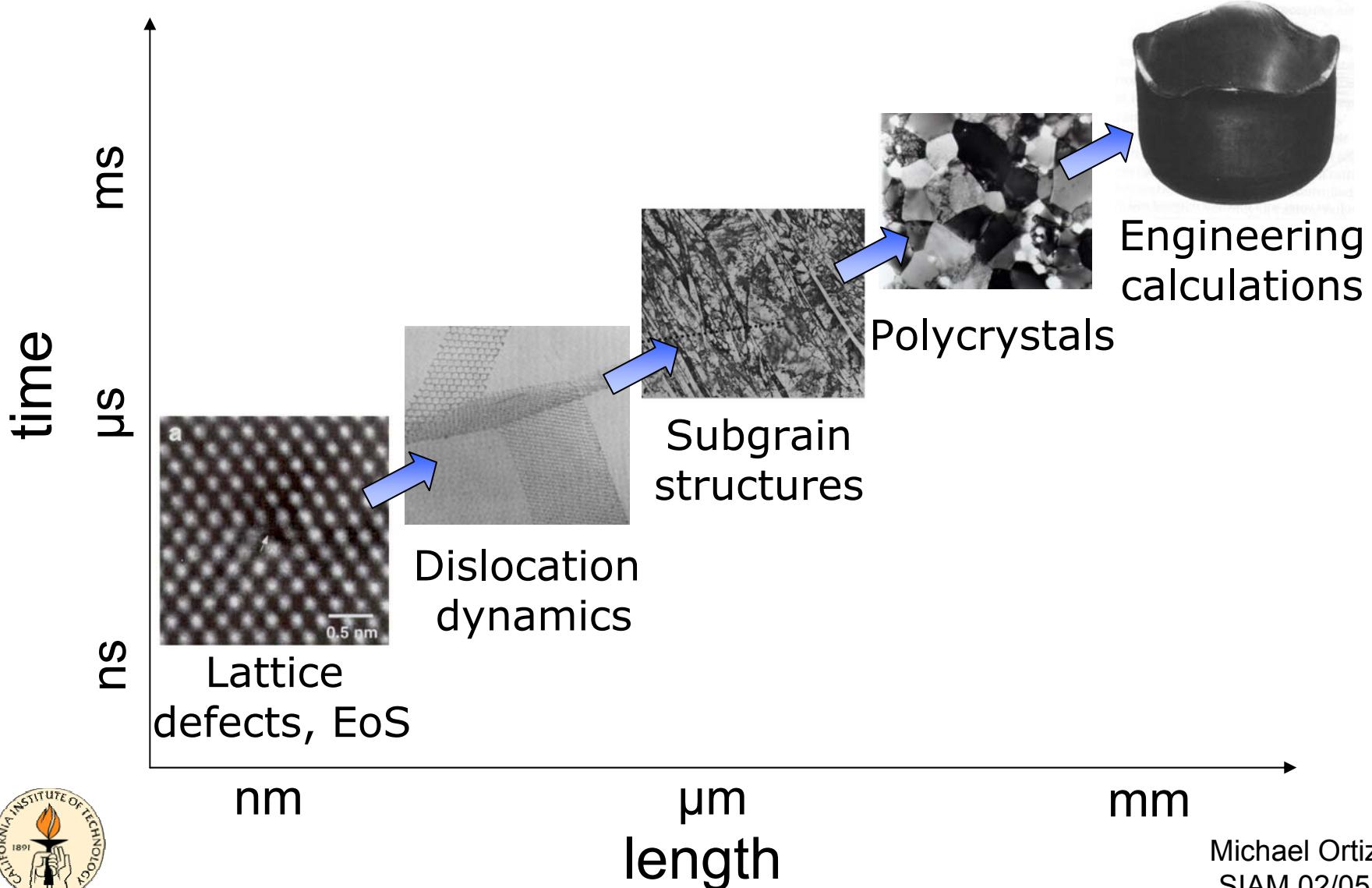
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Introduction

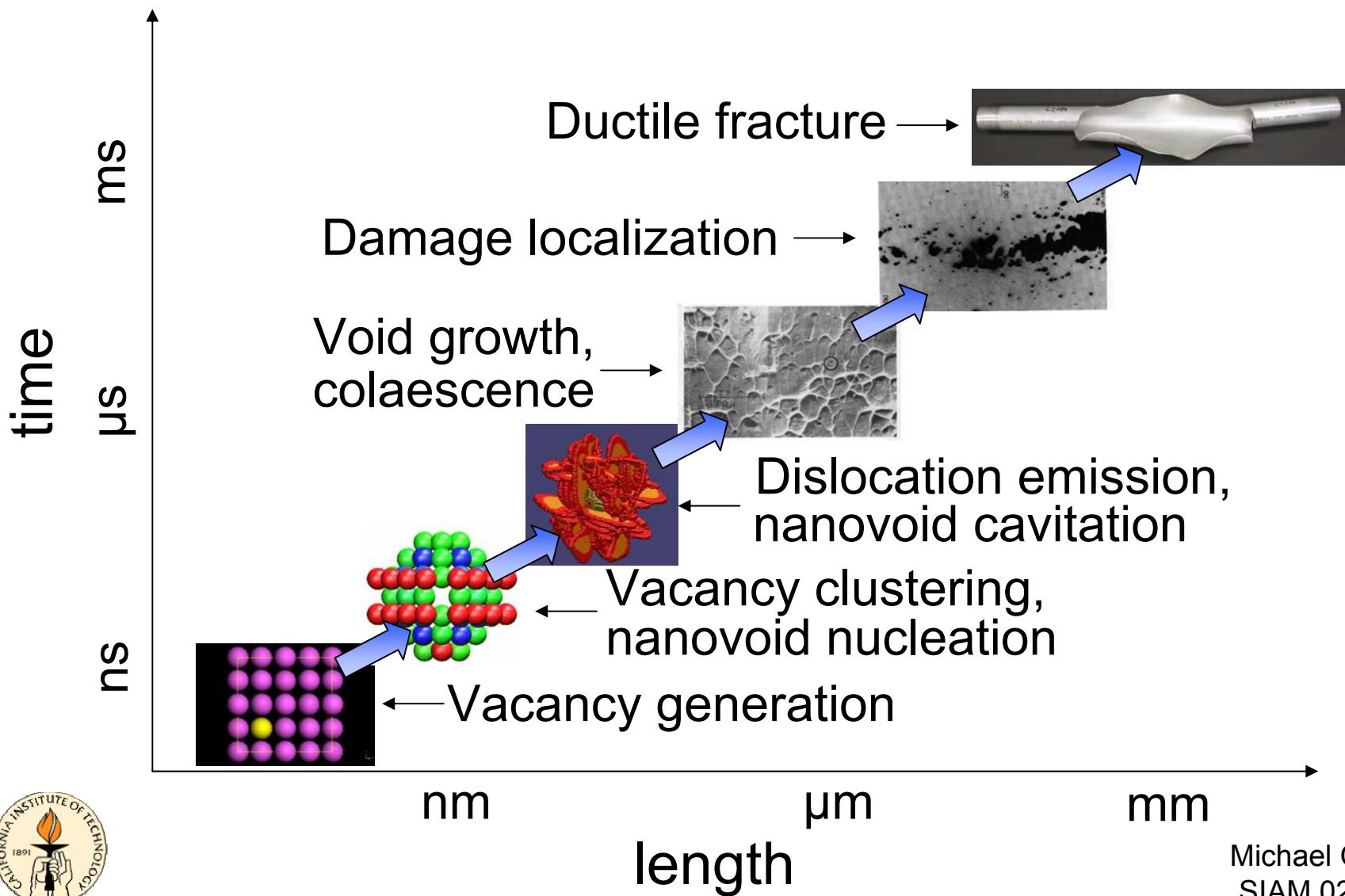
- Multiscale modeling paradigm: Reduce/eliminate uncertainty and empiricism in the simulation of complex materials systems.
- Ultimate goal: Parameter-free (first-principles) predictive simulation.
- Material behavior occurs on multiple length scales; the underlying physics changes from scale to scale.
- Physics provides governing equations at each scale. Bridging of length scales is largely a mathematical/computational problem.



Strength – Multiscale modeling

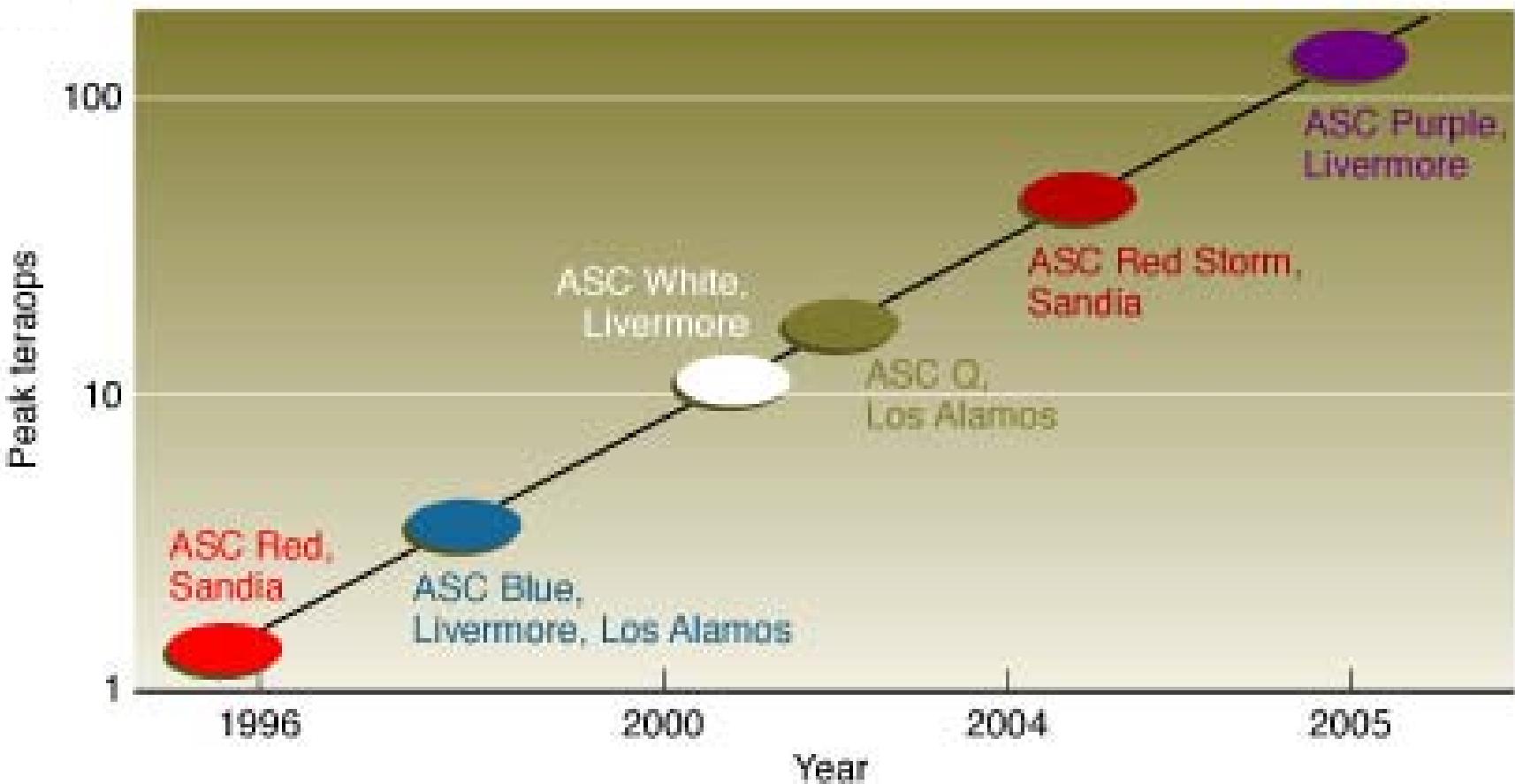


Spall – Lengthscale hierarchy



Direct multiscale computing – Outlook

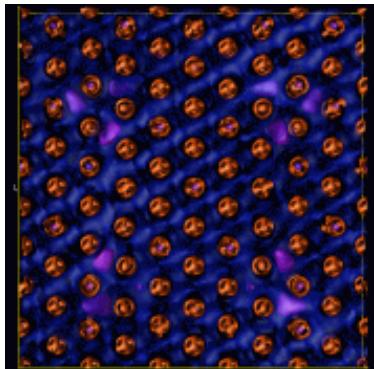
ASC computing systems roadmap



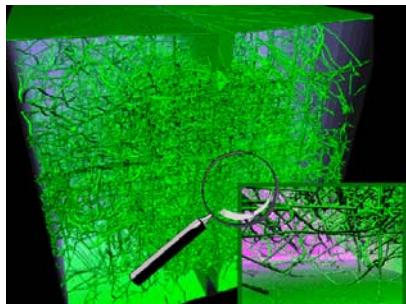
- Computing power is growing rapidly, but...



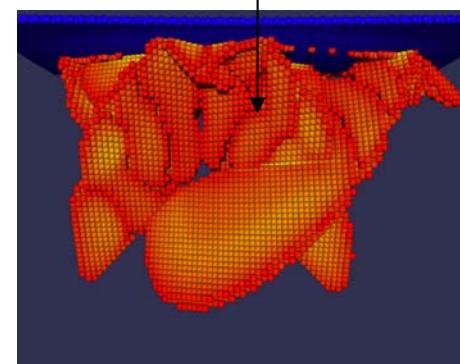
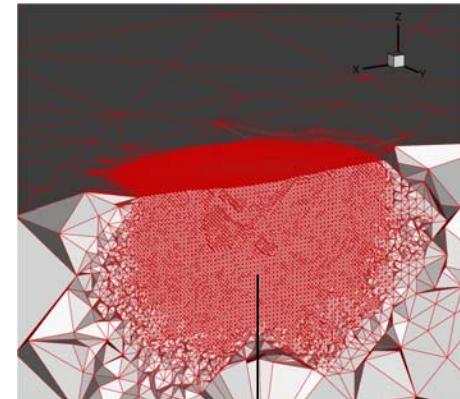
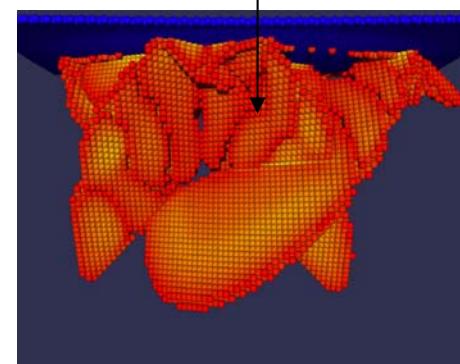
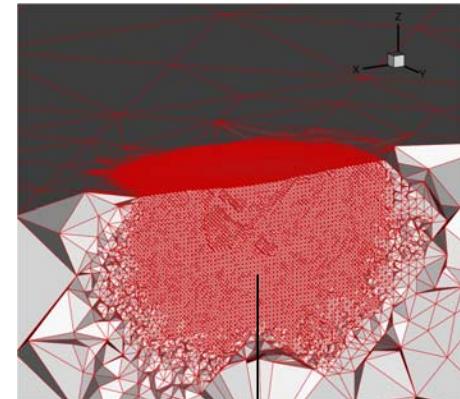
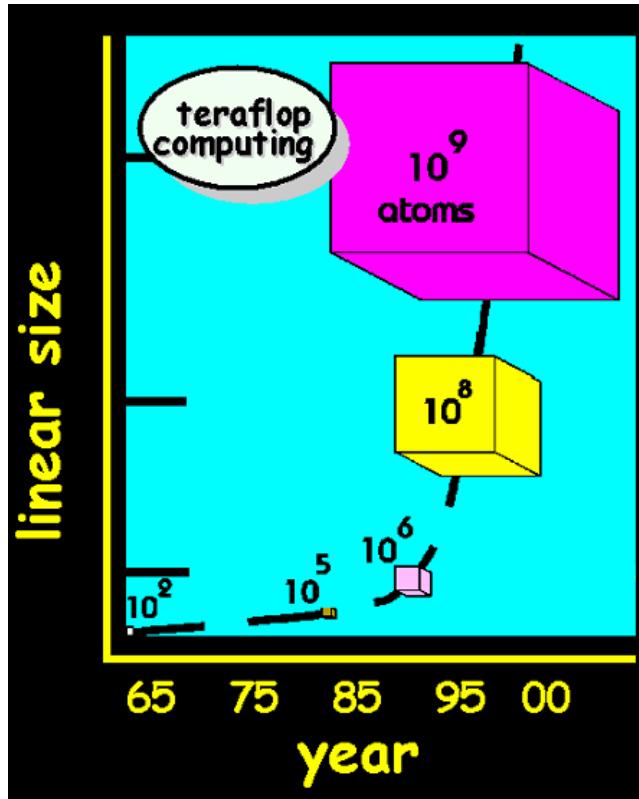
Direct multiscale computing – Outlook



Ta quadrupole
(T. Arias '00)



FCC ductile fracture (Courtesy F.F. Abraham)
(F.F. Abraham '03)

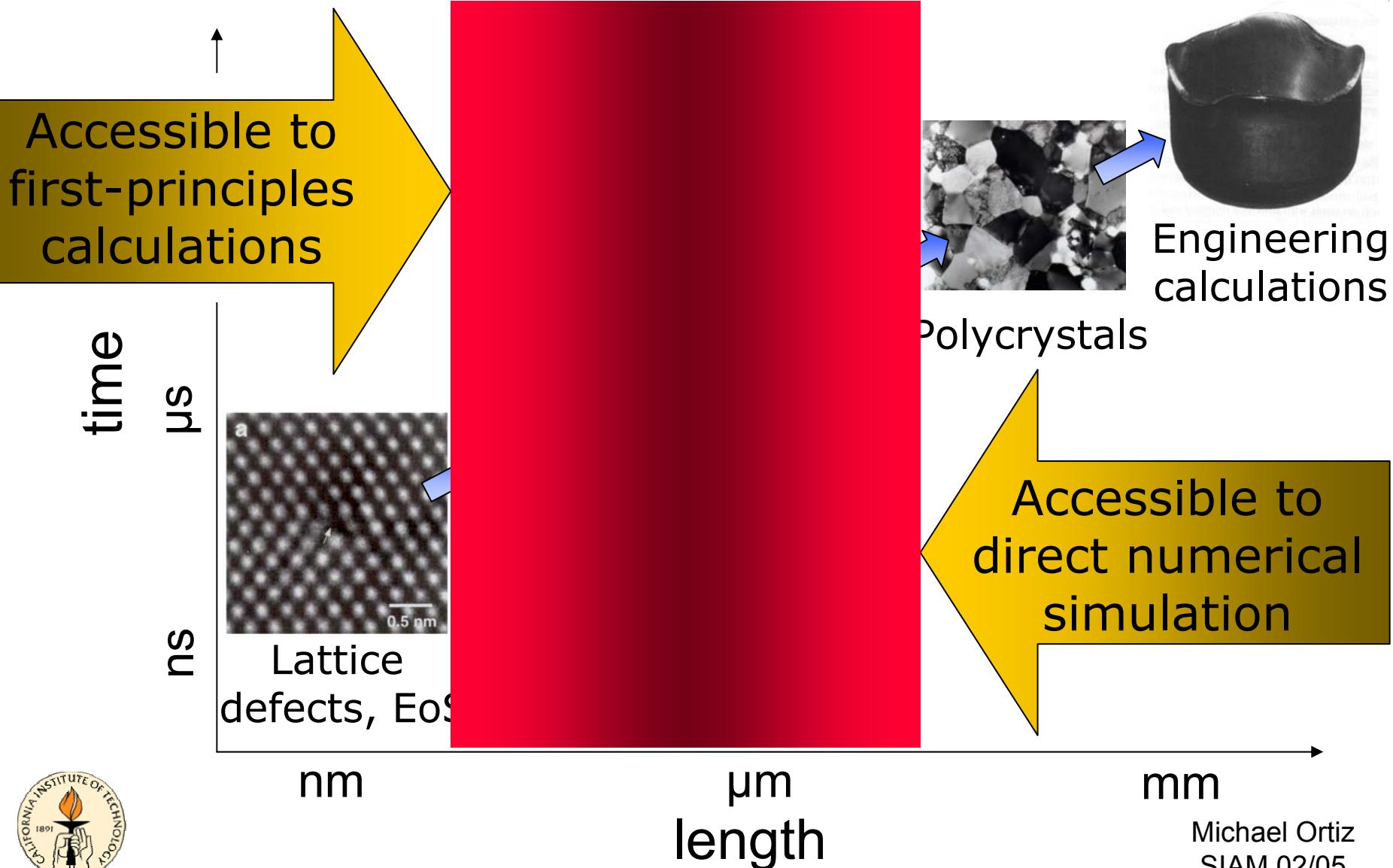


Au nanoindentation
(Knap and Ortiz '03)

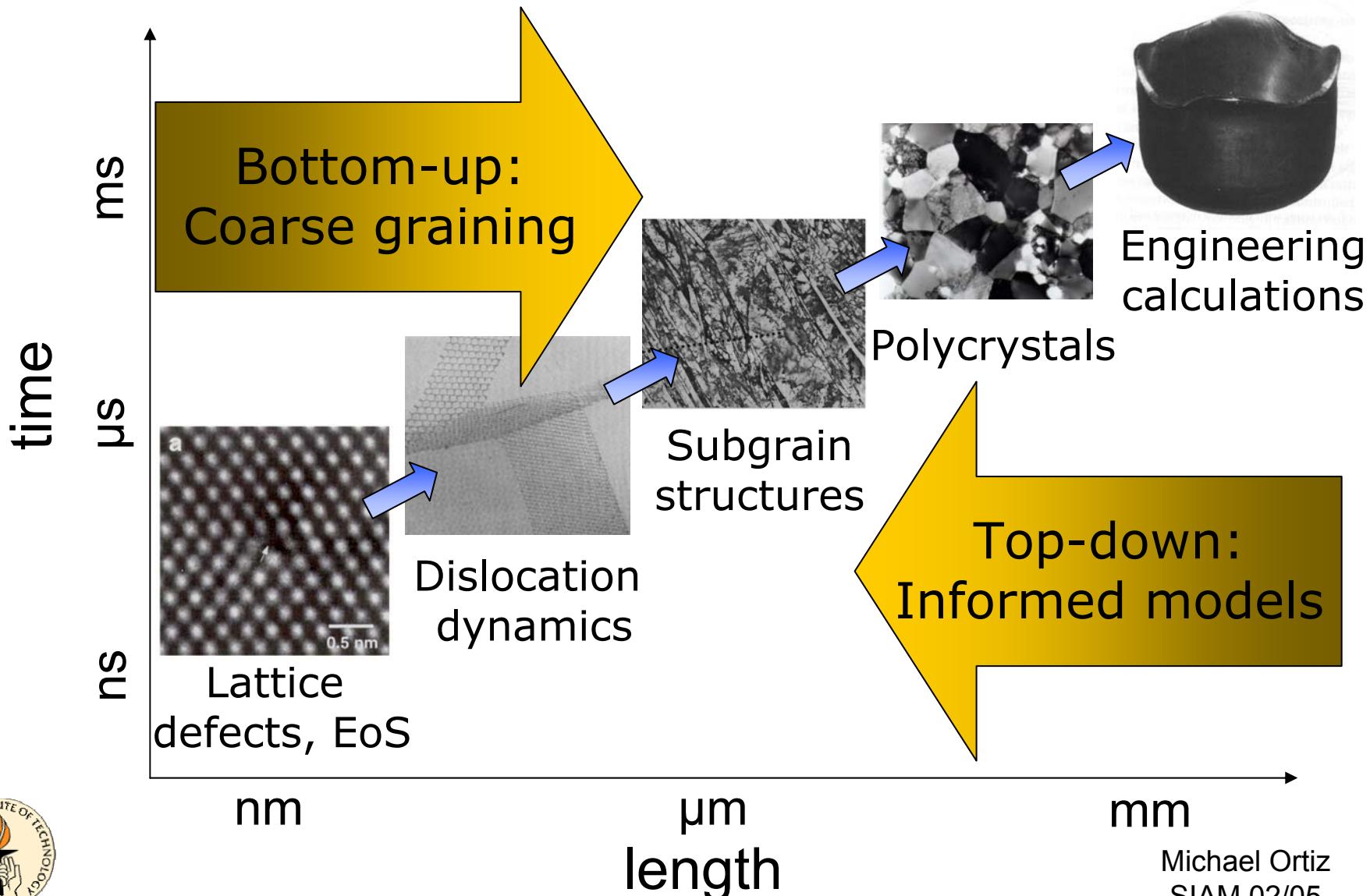
- Computing power is growing rapidly, but
 $10^9 \ll 10^{23}$



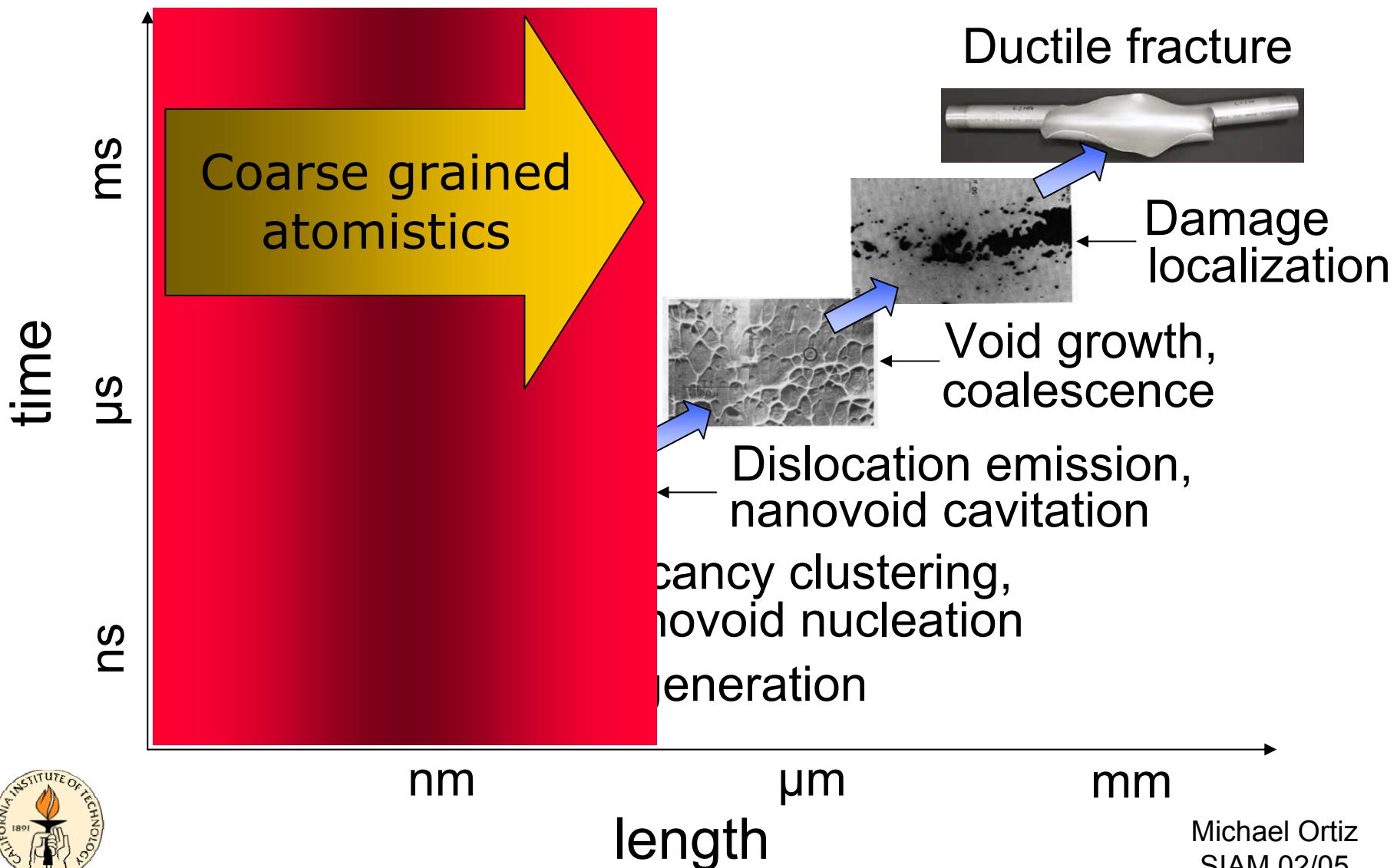
Direct multiscale computing – Outlook



Multiscale modeling – Strategies

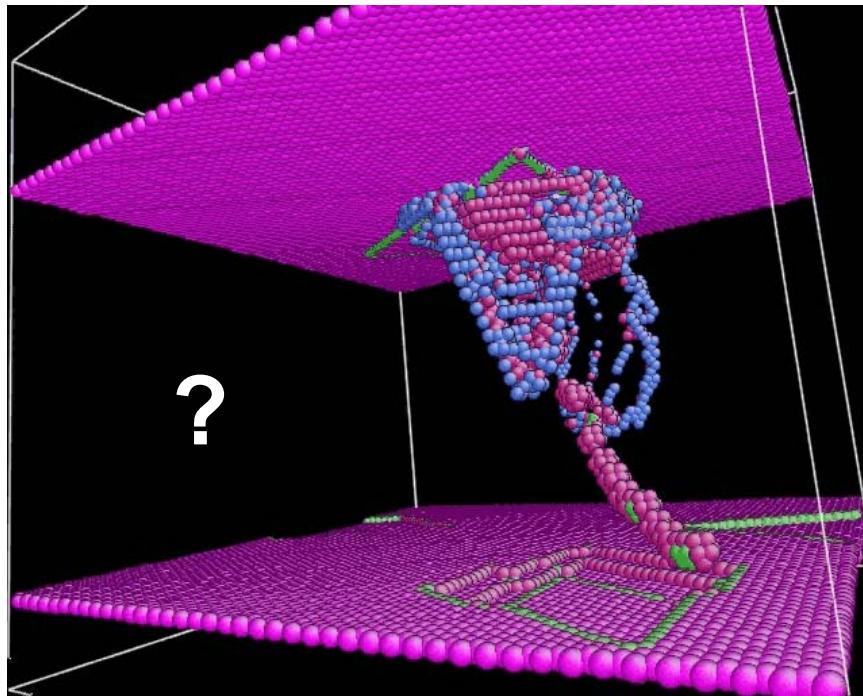


Bottom-up – Quasicontinuum



The case for Quasicontinuum

Au (111) nanoindentation



- Early stages of indentation mediated by defects → Need atomistics
- But elastic (long range) field important → large cells
- Indenter sizes ~ 70 nm, film thickness $\sim 1 \mu\text{m}$ → large cells
- The vast majority of atoms in MD calculations move according to smooth elastic fields → MD wasteful!
- Mixed continuum/ atomistic description.

Li, J., K.J. Van Vliet, T. Zhu, S. Yip, S. Suresh,
"Atomistic mechanisms governing elastic limit
and incipient plasticity in crystals", *Nature*,
418, (2002), 307.



The Quasicontinuum method

Tadmor, Ortiz and Phillips, *Phil. Mag. A*, **76** (1996) 1529.

Knap and Ortiz, *J. Mech. Phys. Solids*, **49** (2001) 1899.

- Total energy:

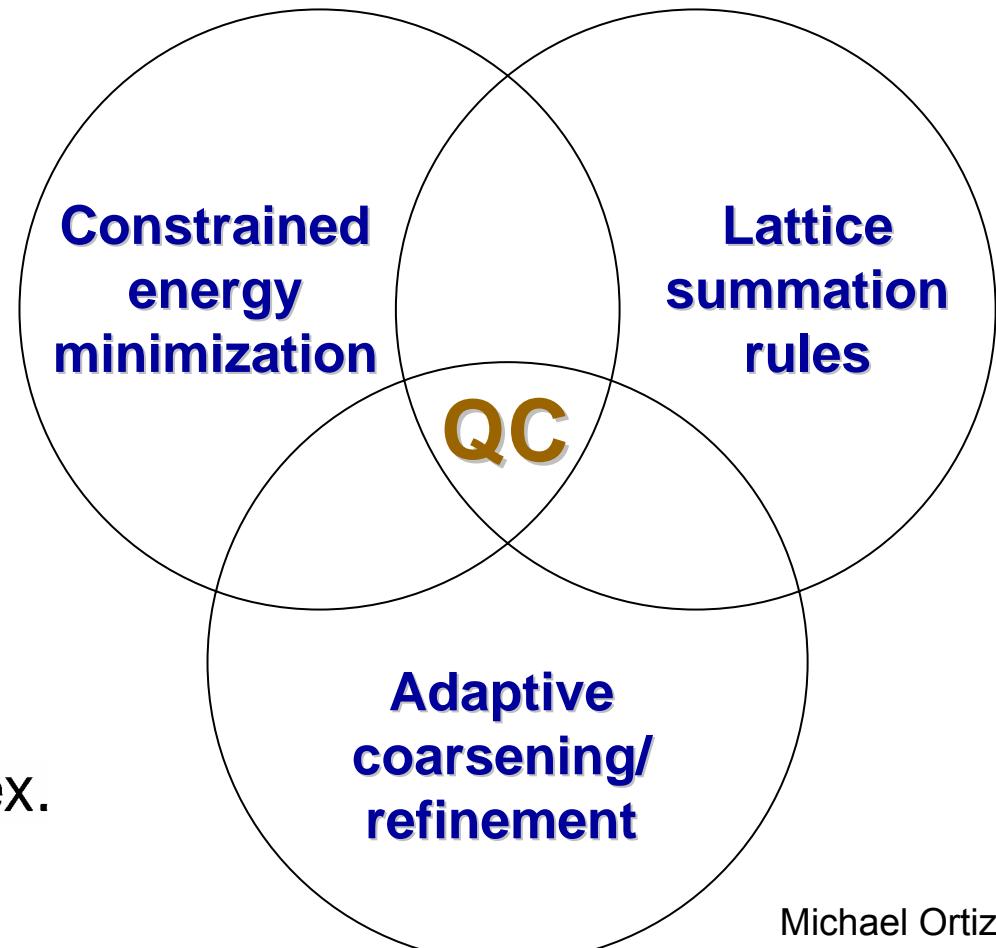
$$E(q), \quad q \in X = \mathbb{R}^N$$

- Problem:

$$\inf_{q \in X} E(q)$$

- Difficulties:

- i) N very large $\sim 10^{23}$
- ii) $E(q)$ highly nonconvex.



Quasicontinuum – Reduction

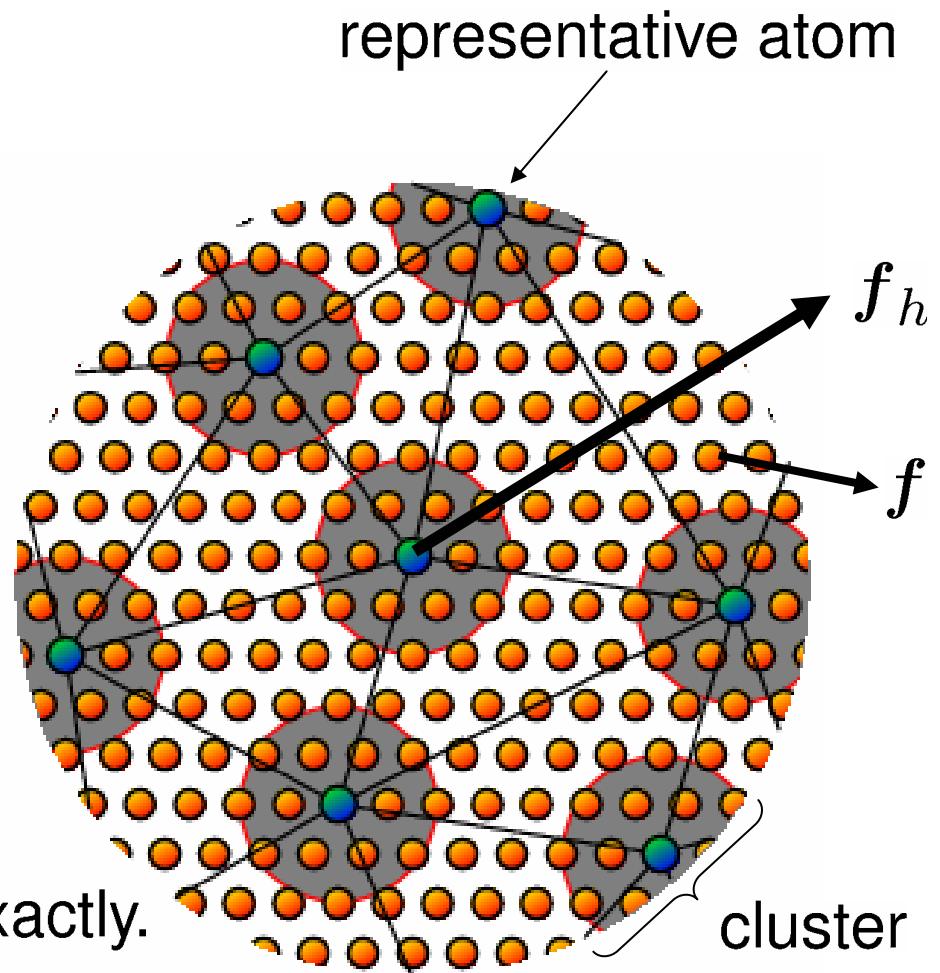
- Reduced problem:

$$\inf_{q \in X_h} E(q)$$

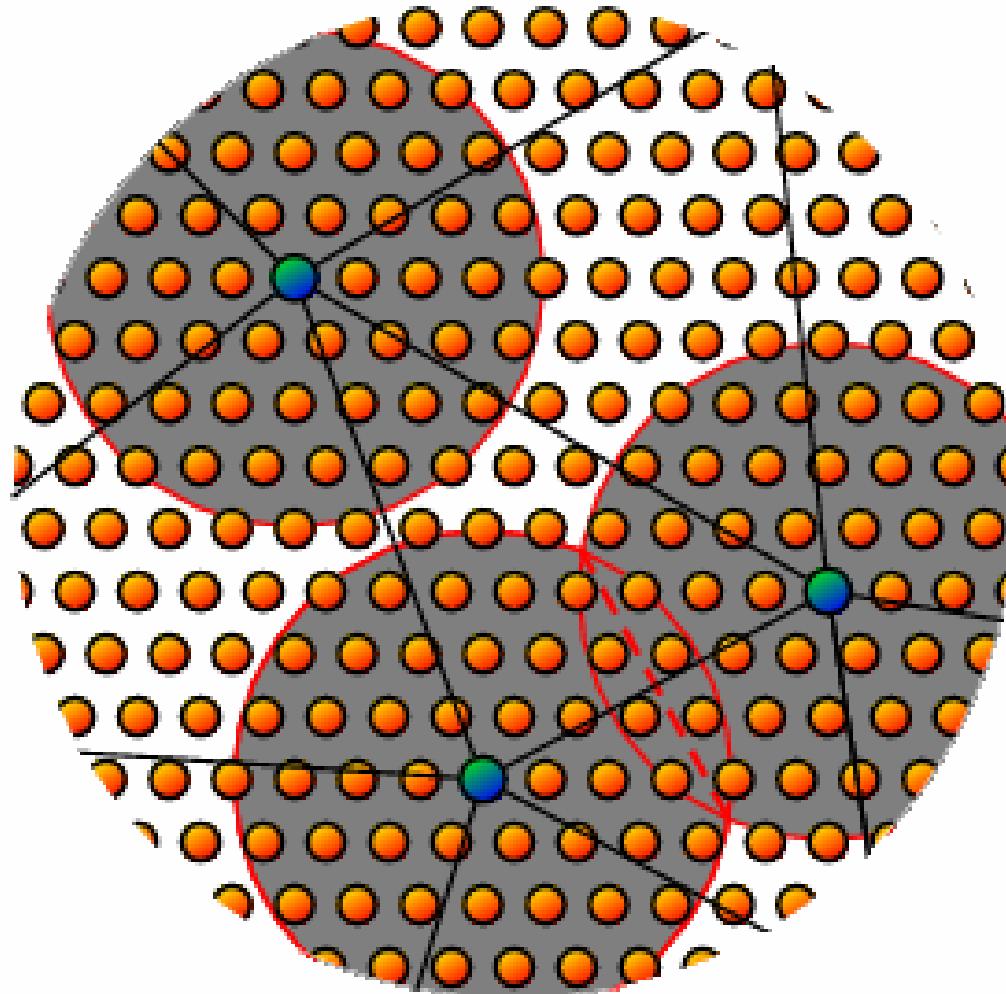
- Cluster summation rule:

$$S_h = \sum_{l_h \in \mathcal{L}_h} n_h(l_h) \sum_{l \in \mathcal{C}(l_h)} f(l),$$

- $n_h(l_h)$ chosen such that basis functions summed exactly.



Quasicontinuum – Cluster sums



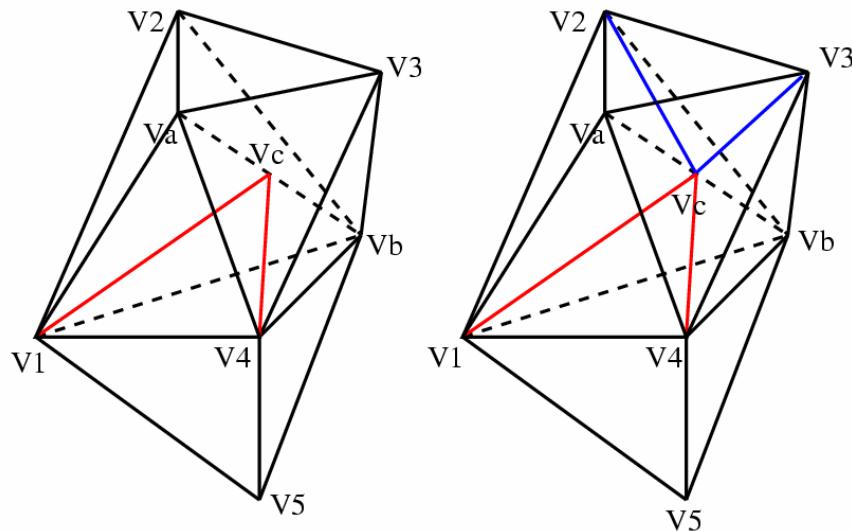
Merging of clusters near atomistic limit



Quasicontinuum – Adaptivity

- $E(K) \equiv$ Lagrangian strain in simplex K
- Refinement criterion: *Bisect* K if

$$|E(K)| \geq \text{TOL} \frac{b}{h(K)}$$

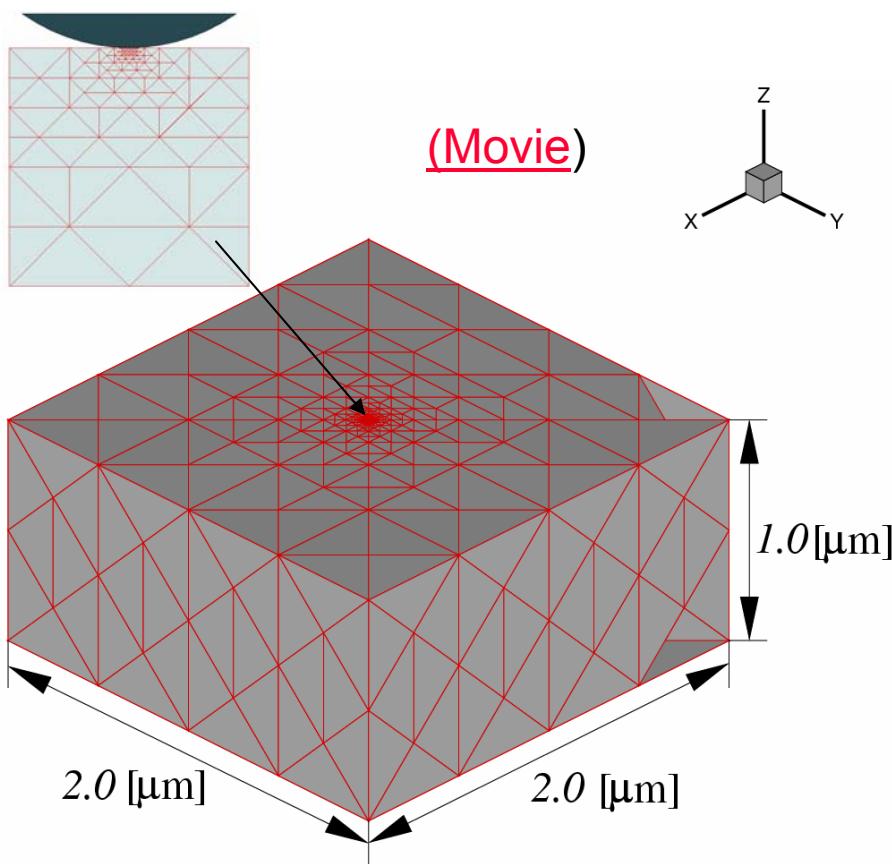


Longest-edge bisection of tetrahedron (1,4,a,b) along longest edge (a,b) and of ring of tetrahedra incident on (a,b)

- TOL chosen s. t. dislocations have atomistic core.



QC - Nanoindentation of [001] Au



- Nanoindentation of [001] Au, 2x2x1 micrometers
- Spherical indenter, $R=7$ and 70 nm
- Johnson EAM potential
- Total number of atoms $\sim 0.25 \cdot 10^{12}$
- Initial number of nodes $\sim 10,000$
- Final number of nodes $\sim 100,000$

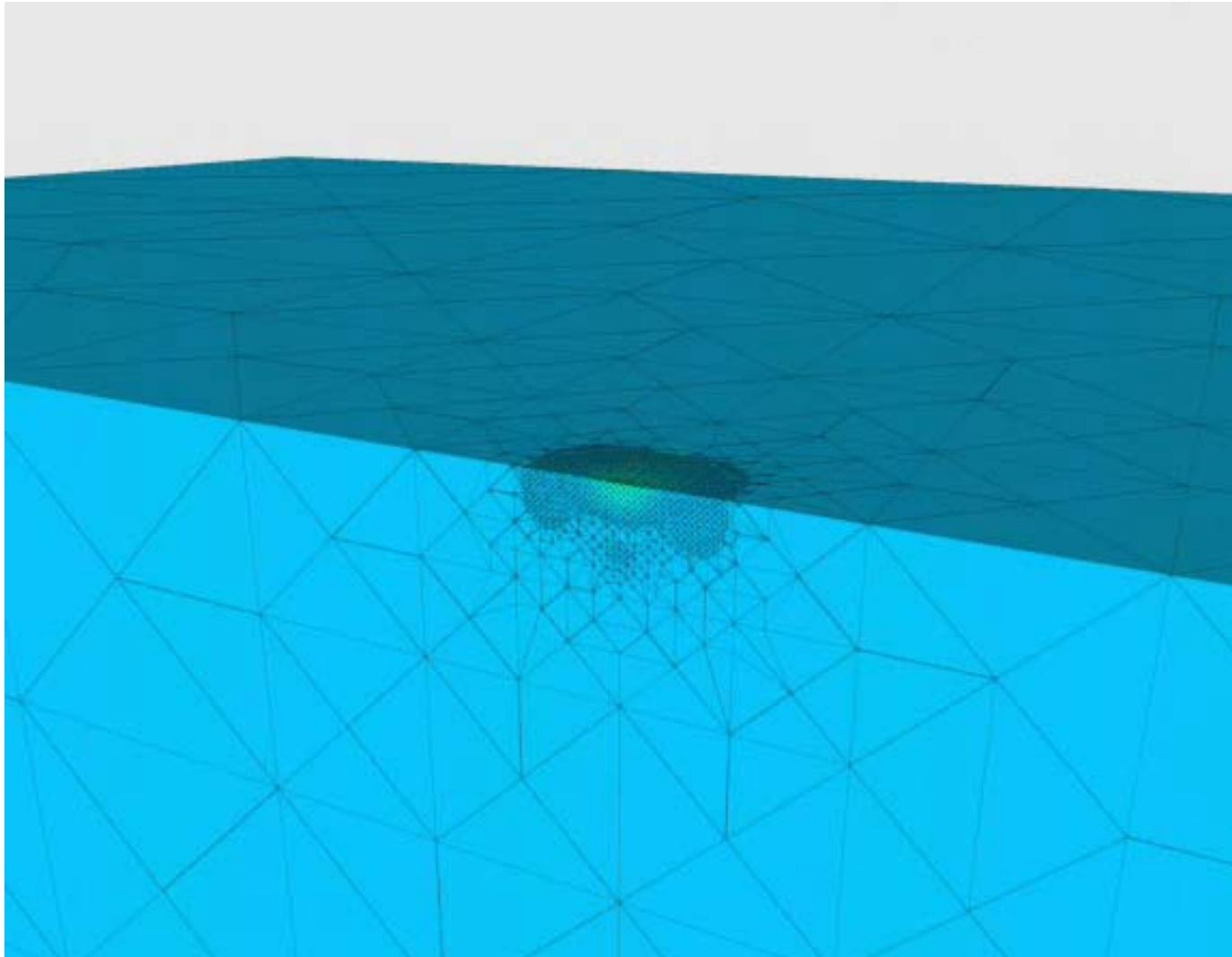
Detail of initial computational mesh

(Knap and Ortiz, *PRL* **90** 2002-226102)

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QC - Nanoindentation of [001] Au

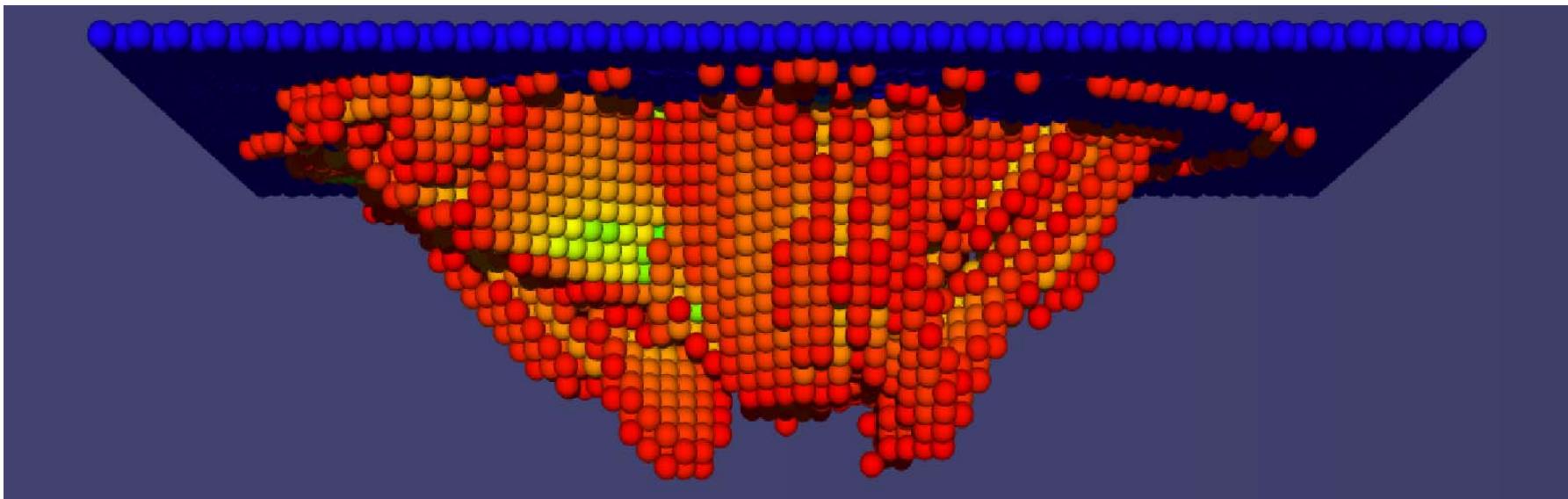


(Knap and Ortiz, *PRL* **90** 2002-226102)



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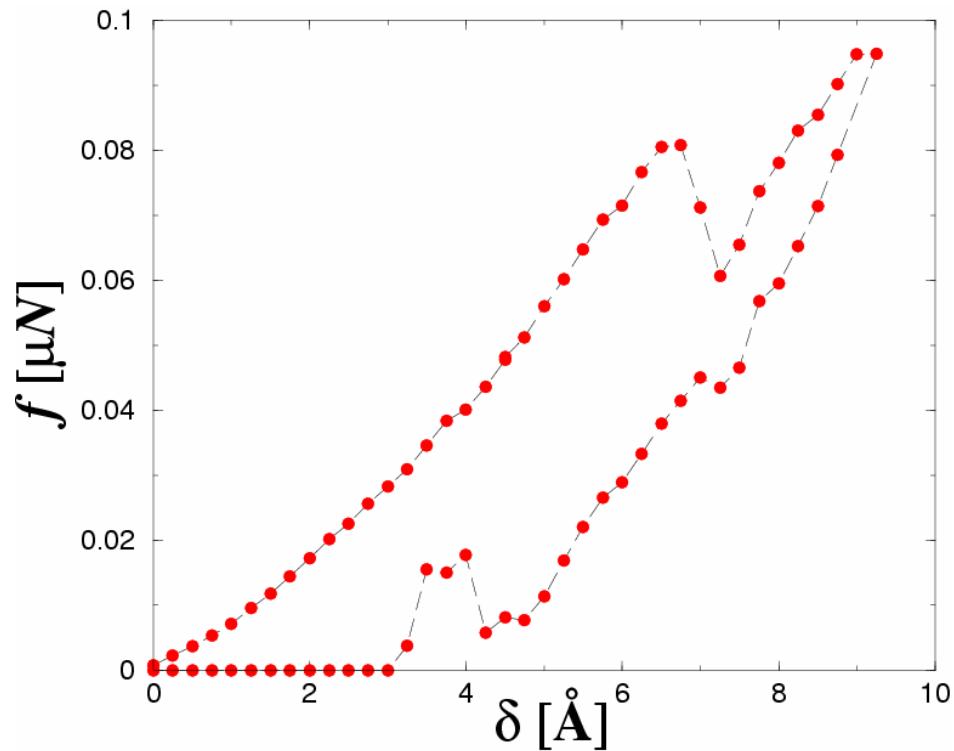
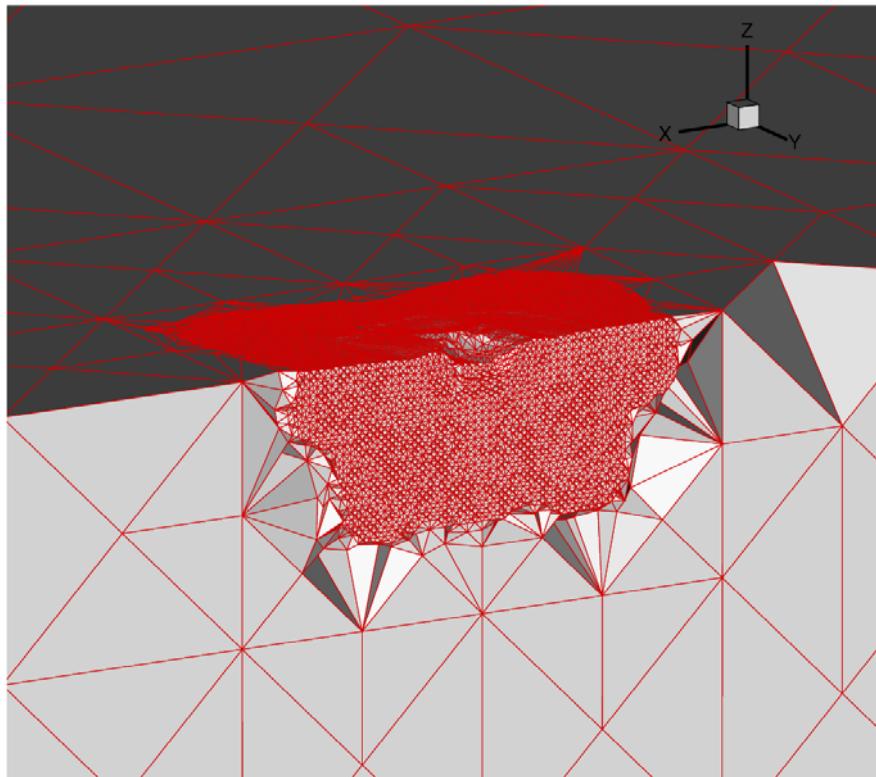
QC - Nanoindentation of [001] Au



7 nm indenter, depth = 0.92 nm



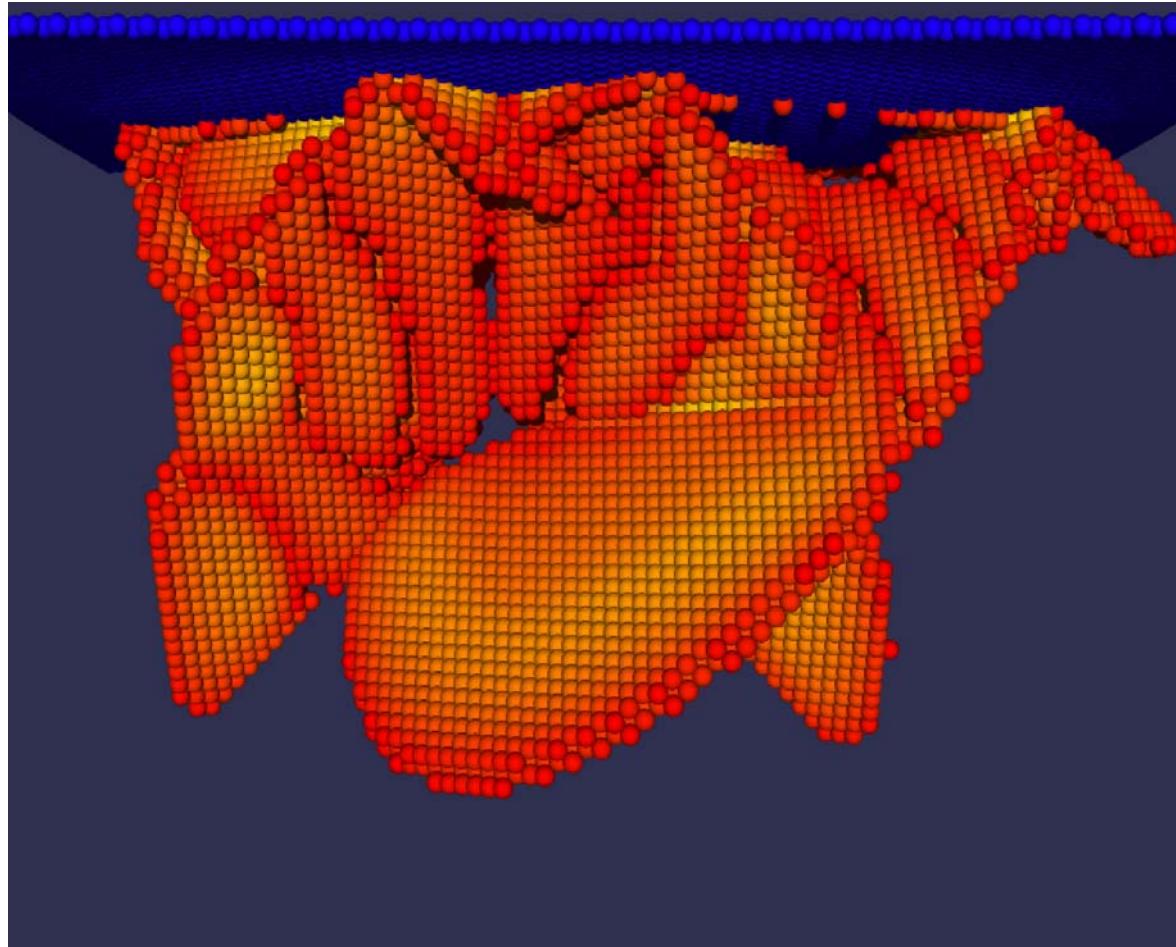
QC - Nanoindentation of [001] Au



7 nm indenter, depth = 0.92 nm



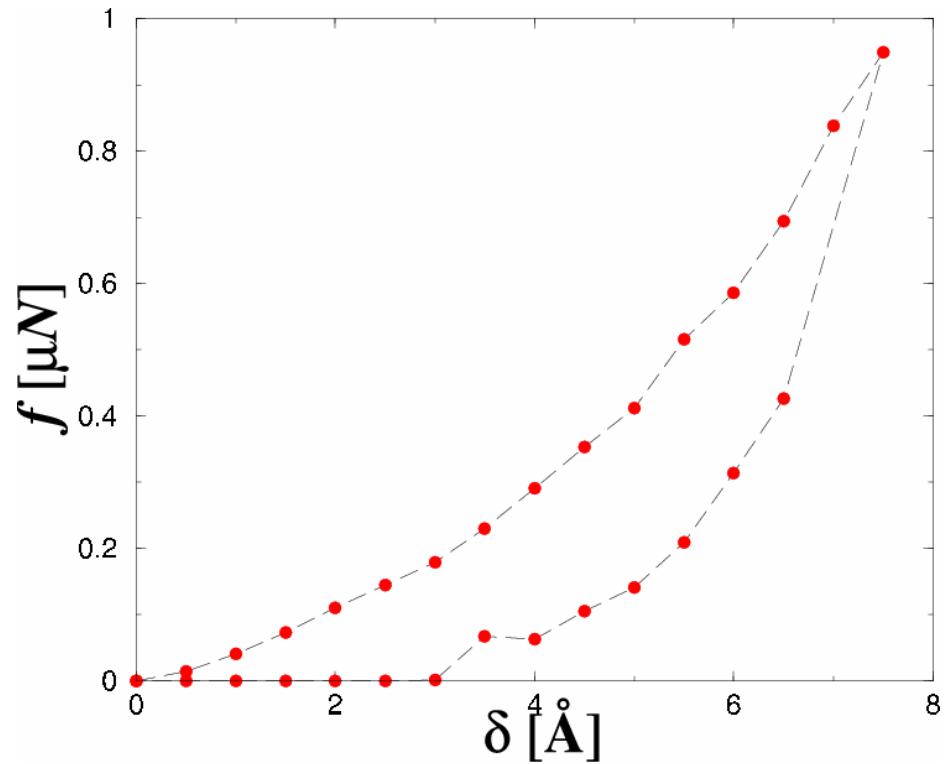
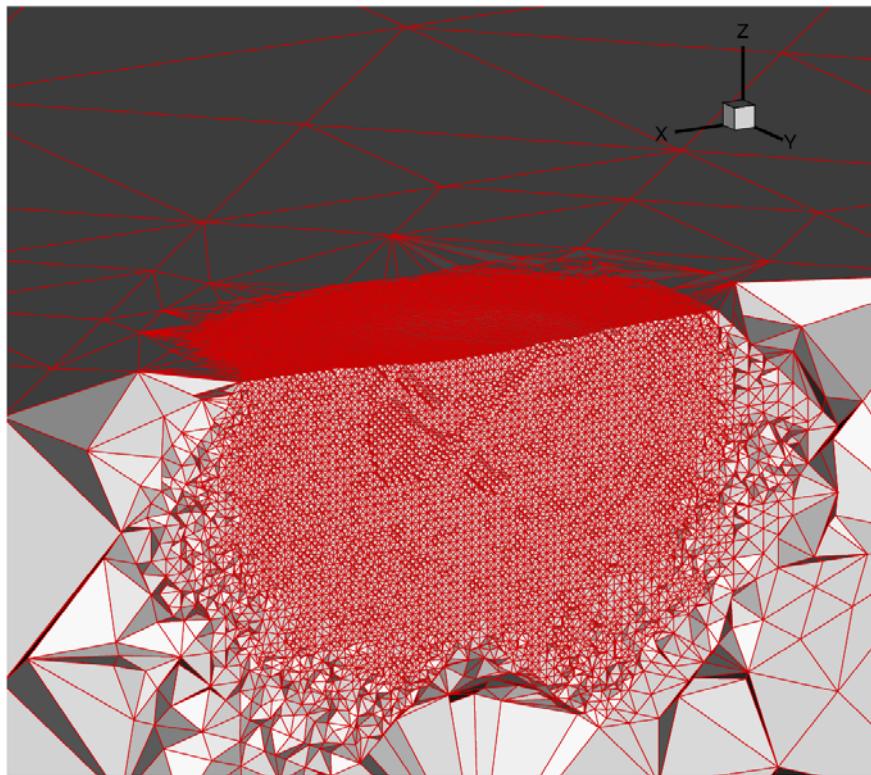
QC - Nanoindentation of [001] Au



70 nm indenter, depth = 0.75 nm



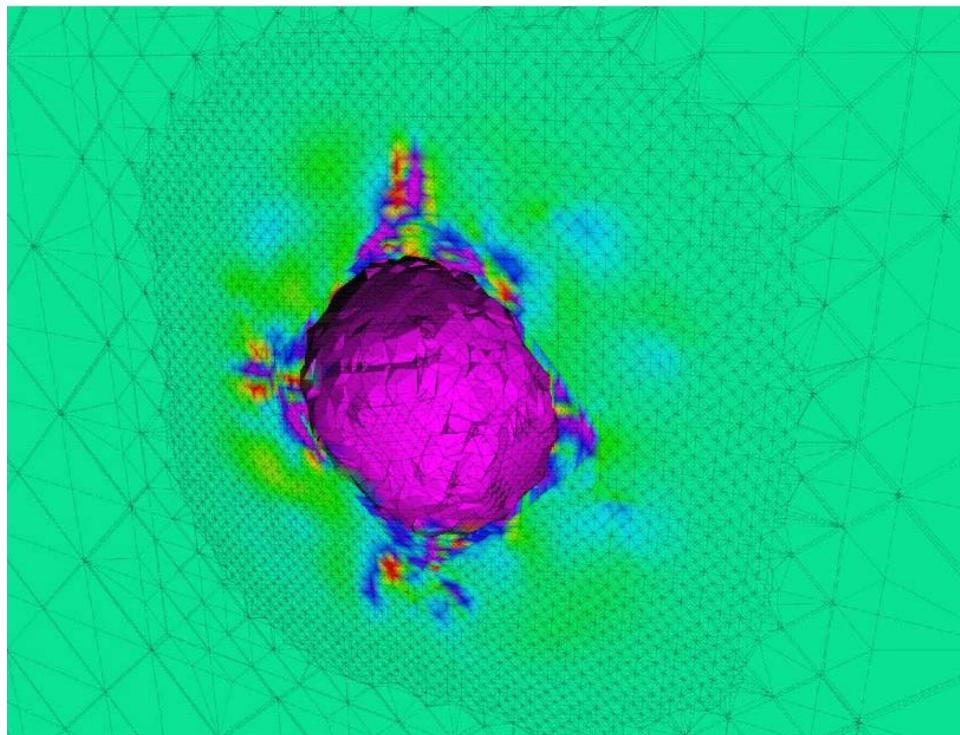
QC - Nanoindentation of [001] Au



70 nm indenter, depth = 0.75 nm



QC - Nanovoid cavitation in Al



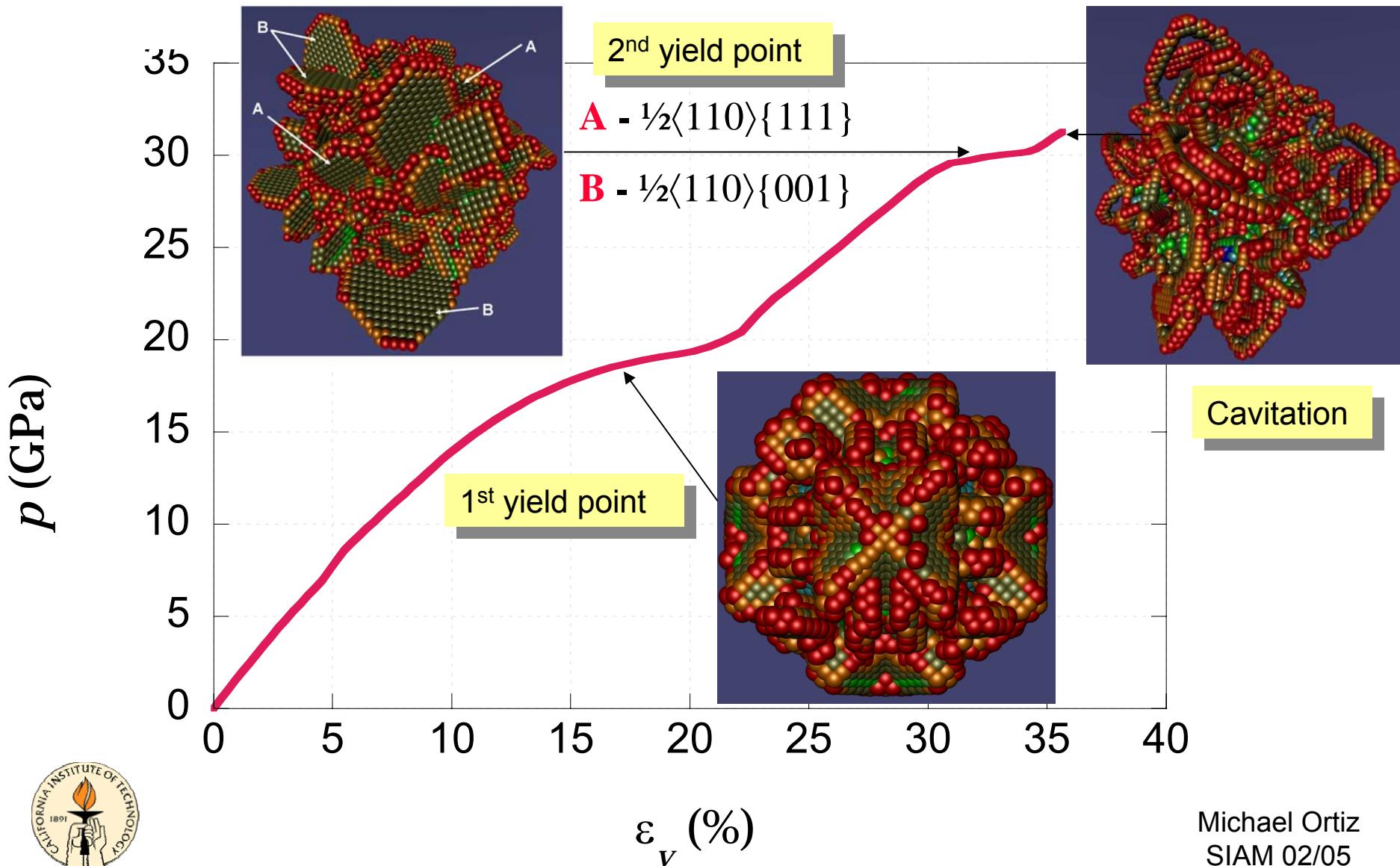
Close-up of internal void
and adapted mesh at $\varepsilon_v = 30.8\%$

- 72x72x72 cell sample
- Initial radius $R=2a$
- Ercolessi and Adams (*Europhys. Lett.* **26**, 583, 1994) EAM potential.
- Total number of atoms $\sim 16 \times 10^6$
- Initial number of nodes $\sim 34,000$

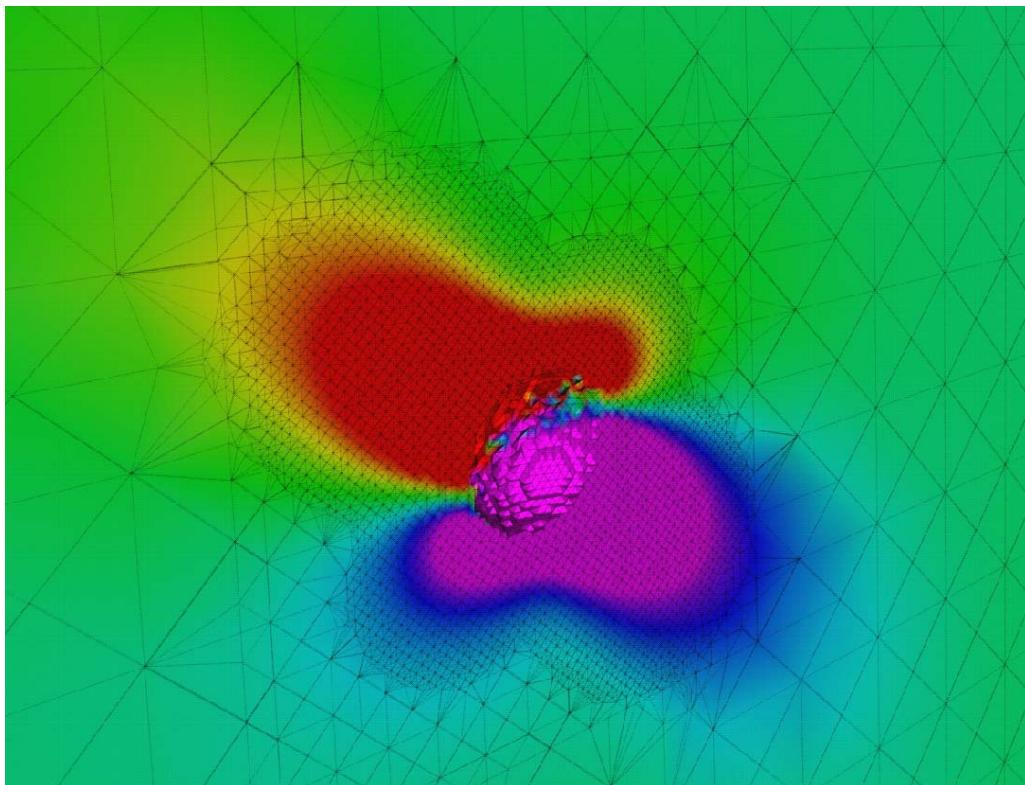


QC calculations of nanovoid cavitation in EAM Al
(Marian, Knap and Ortiz, PRL '04)

QC – Nanovoid cavitation in Al



QC – Nanovoid shearing in Al



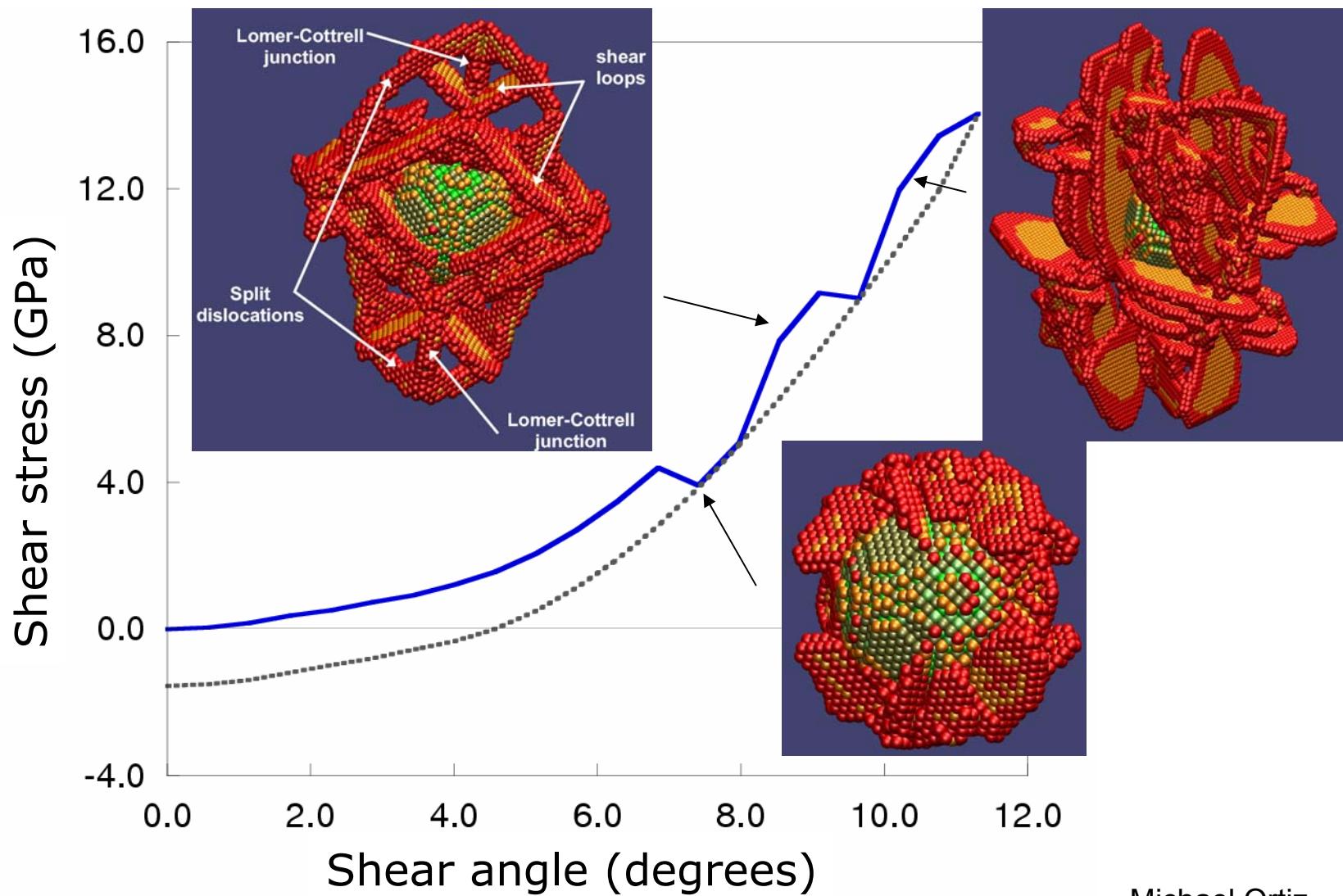
- 72x72x72 cell sample
- Initial radius $R=2a$
- Ercolessi and Adams (*Europhys. Lett.* **26**, 583, 1994) EAM potential.
- Total number of atoms $\sim 16 \times 10^6$
- Initial number of nodes $\sim 34,000$

Close-up of internal void and adapted mesh at $\gamma = 12\%$

QC calculations of nanovoid shearing in EAM Al
(J. Marian, J. Knap and M. Ortiz, '05)



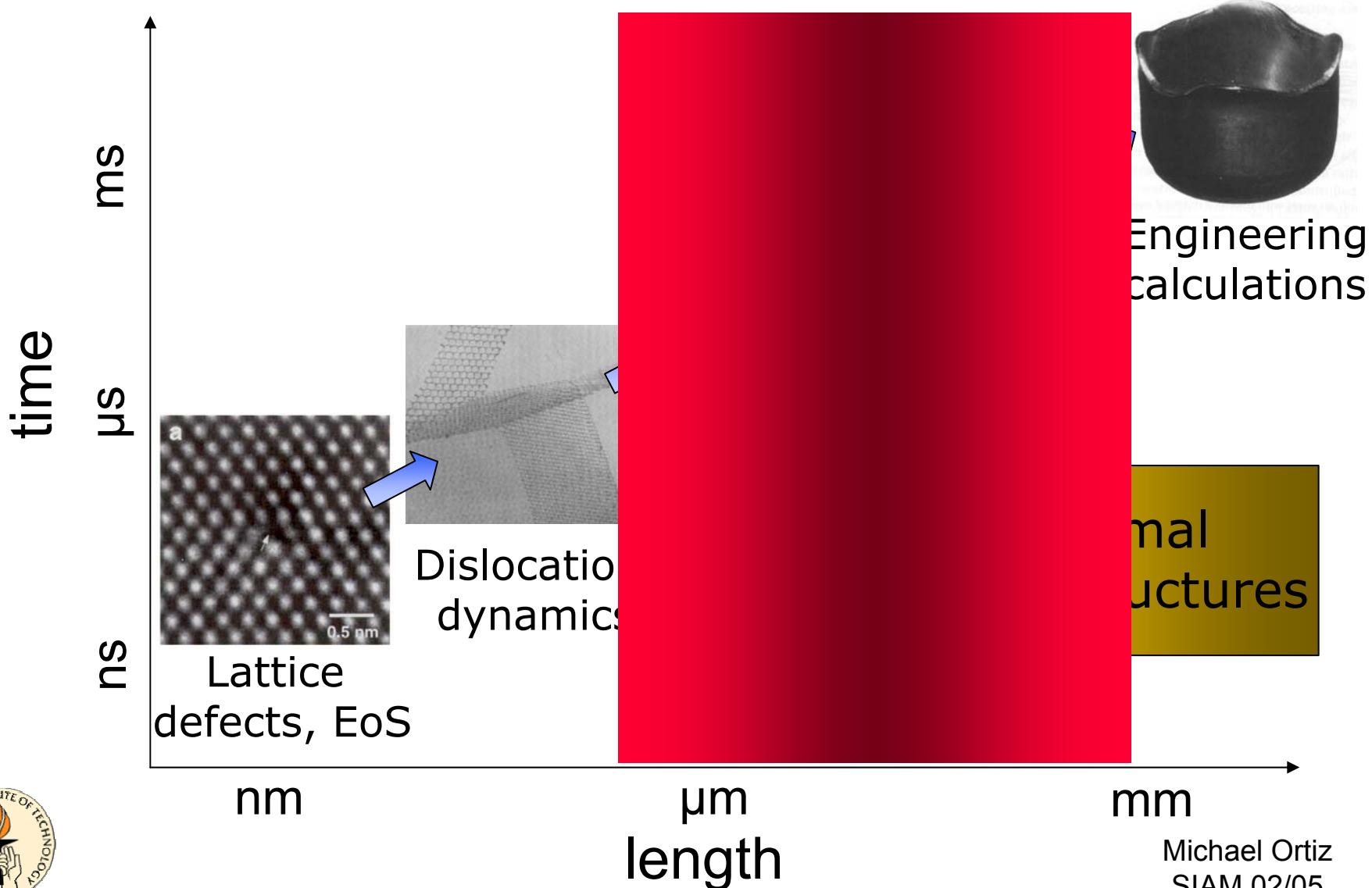
QC - Nanovoid cavitation in Al



Quasicontinuum – Outlook

- The Quasicontinuum method is an example of a bottom-up multiscale method based on:
 - *Coarse-graining (kinematic constraints)*
 - *Sampling (clusters)*
 - *Adaptivity (spatially adapted resolution)*
- The Quasicontinuum method is an example of a *concurrent multiscale computing*: it resolves continuum and atomistic lengthscales concurrently during same calculation
- Challenges:
 - *Dynamics (internal reflections)*
 - *Finite temperature (heat conduction)*
 - *Transition to dislocation dynamics*

Top-down – Relaxation



Framework – Calculus of variations

Problem. For $F : X \rightarrow \bar{\mathbb{R}}$, find:

$$\begin{cases} m_X(F) = \inf_{u \in X} F(u) \\ M_X(F) = \{u \in X, \text{ s. t. } F(u) = m_X(F)\} \end{cases}$$

Theorem. Let $F : X \rightarrow \bar{\mathbb{R}}$ be lower-semicontinuous and coercive. Then F has a minimum point in X . If, in addition, F is convex, then the minimizer is unique.

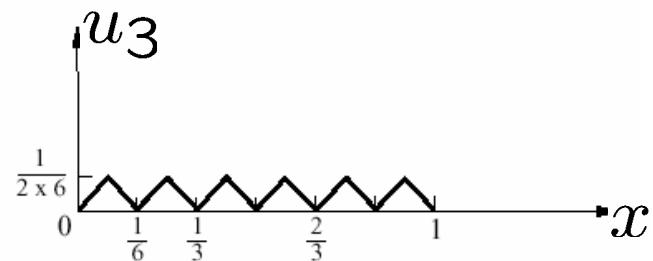
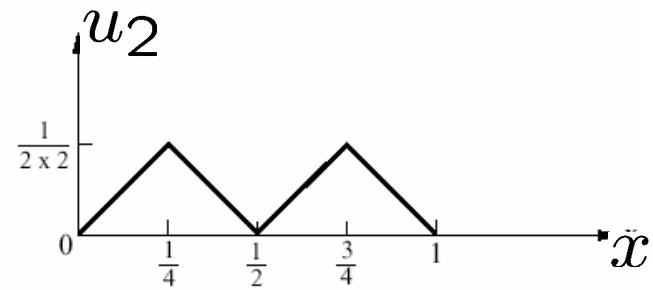
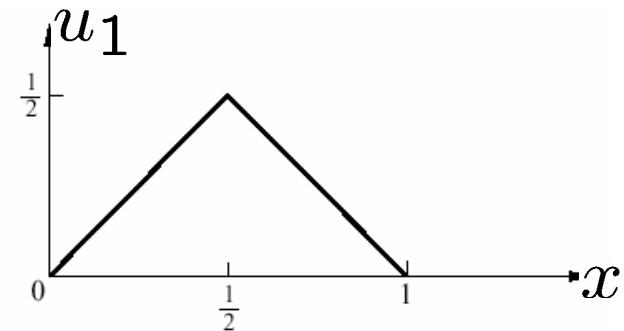
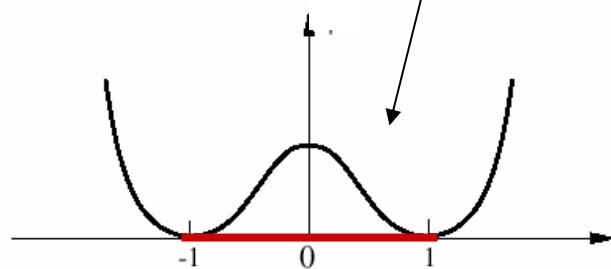
- Many functions F of interest lack lower-semicontinuity
⇒ infimum not attained.
- Direct numerical solutions exhibit exceedingly slow or no convergence!



Lack of l.s.c. and microstructure

Example. $X = W_0^{1,\infty}([0, 1])$,

$$F(u) = \int_0^1 [u^2 + \underbrace{(u_x^2 - 1)^2}_{\text{Microstructure}}] dx$$



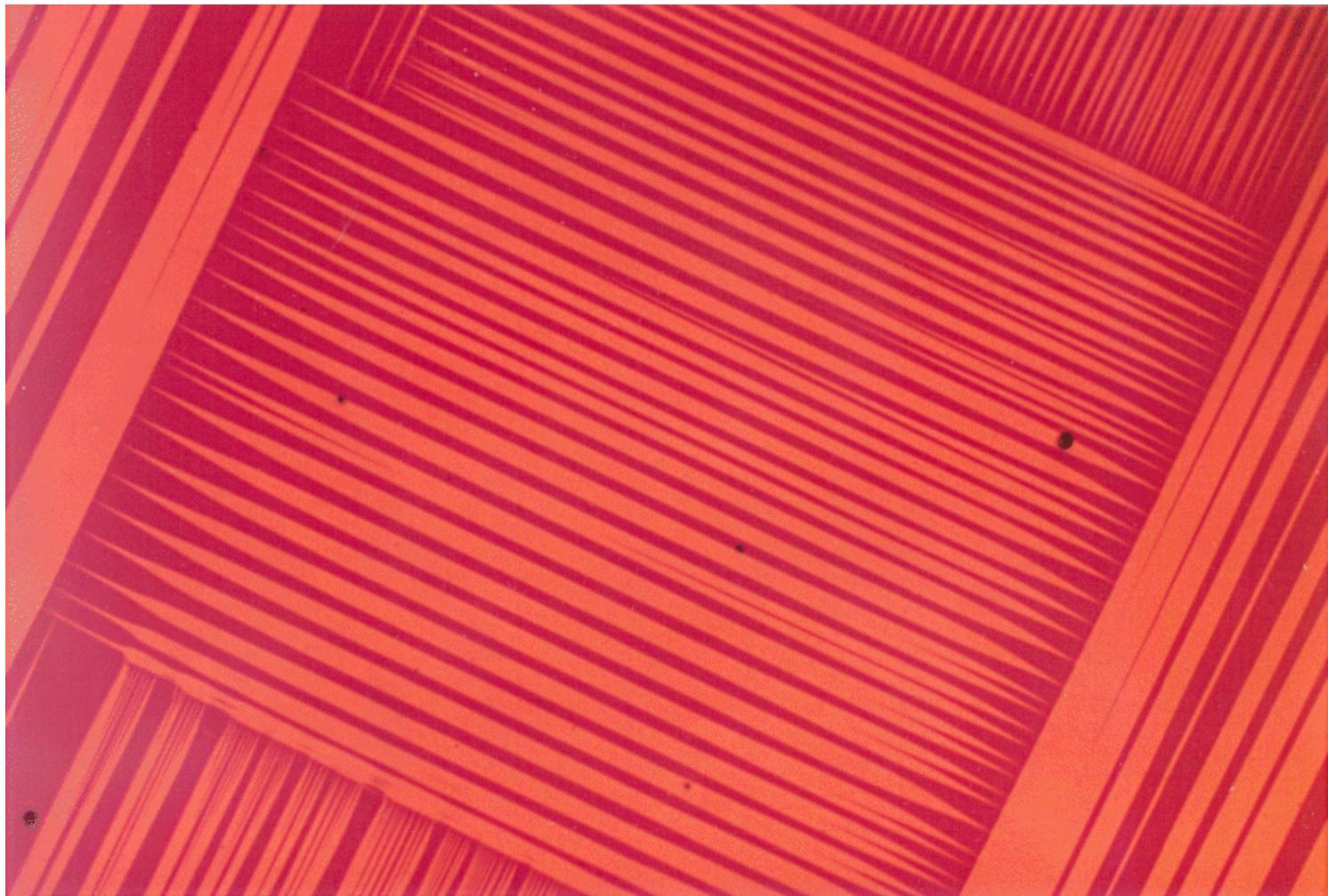
$\exists u_j \rightarrow 0$ in $W_0^{1,\infty}([0, 1])$

$u_j \rightarrow 0$ in $L^2([0, 1])$

s. t. $F(u_j) \rightarrow 0 \leq F(0) = 1$



Microstructure of martensite in Cu-Al-Ni

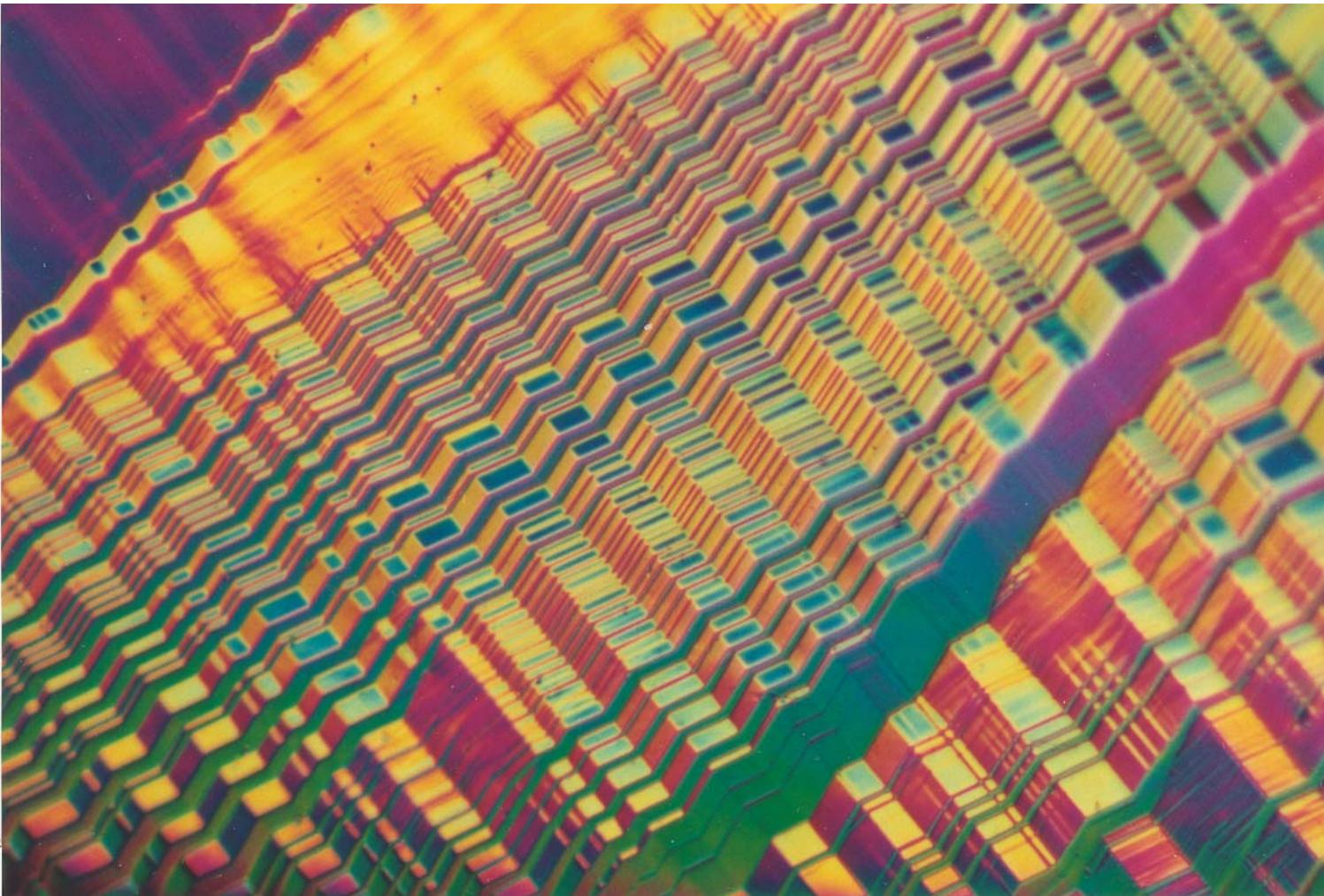


Cu-Al-Ni, C. Chu and R. D. James



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Microstructure of martensite in Cu-Al-Ni

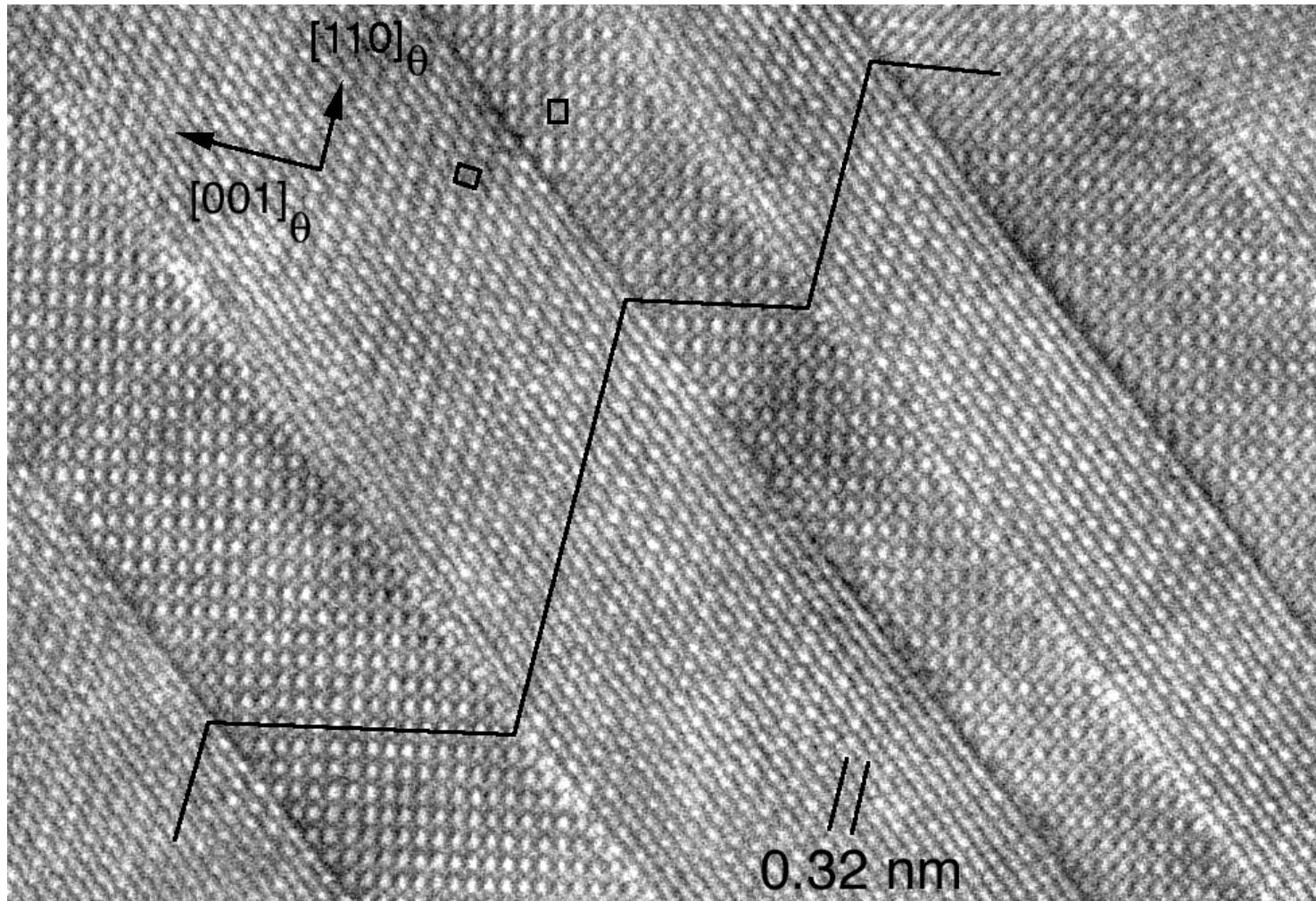


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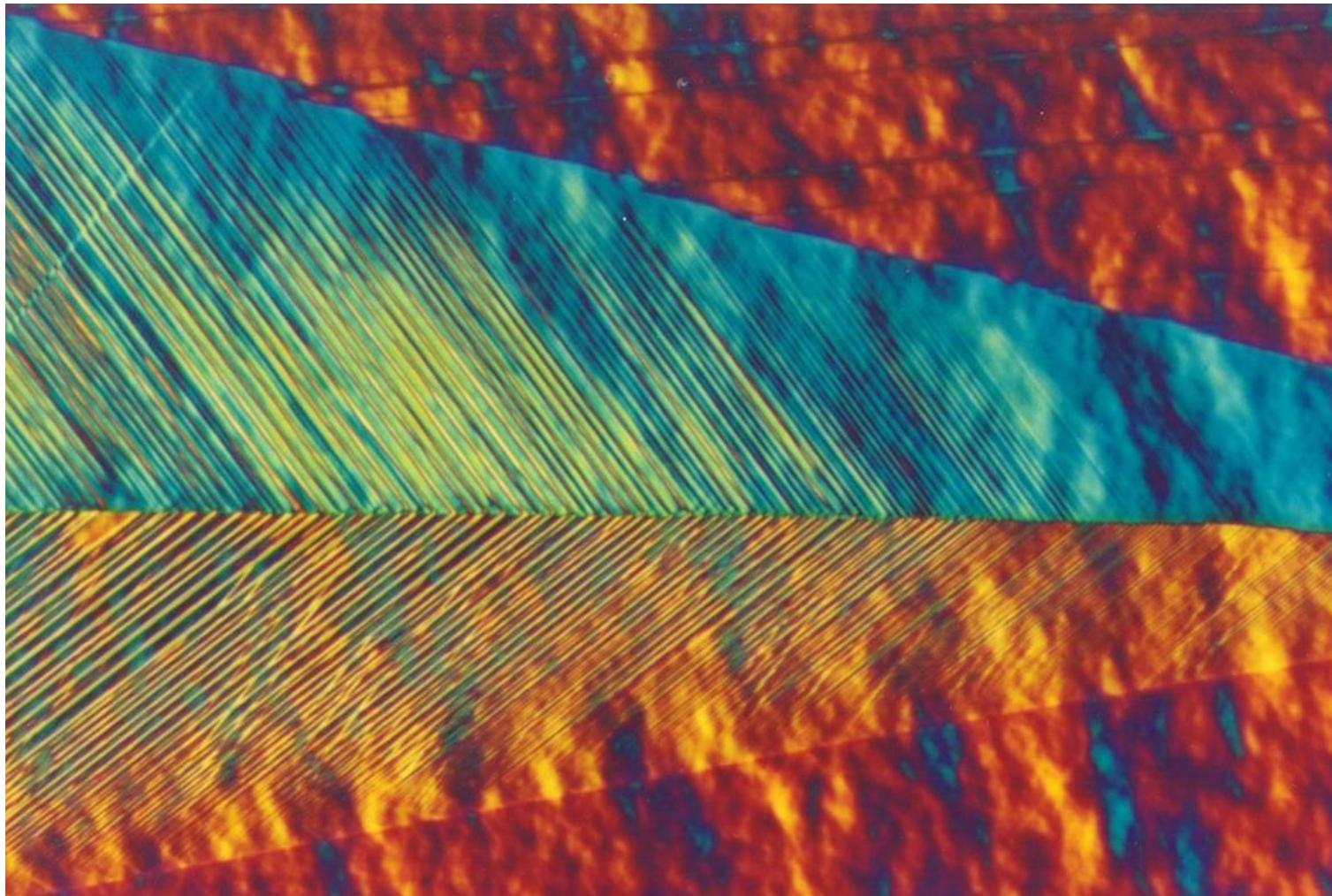
Fine twins in Ni-Al



Ni-Al, Dominique Schryvers

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Wedge-like microstructure in Cu-Al-Ni



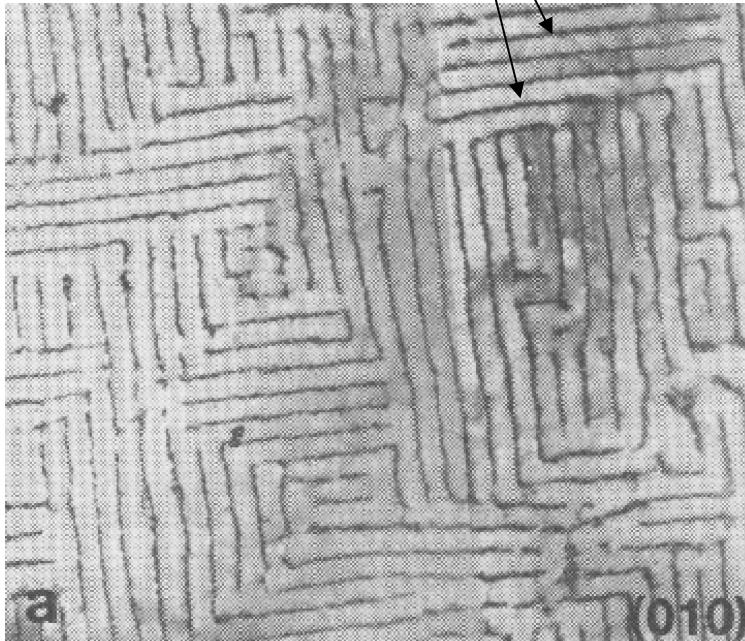
Cu-Al-Ni, C. Chu and R. D. James

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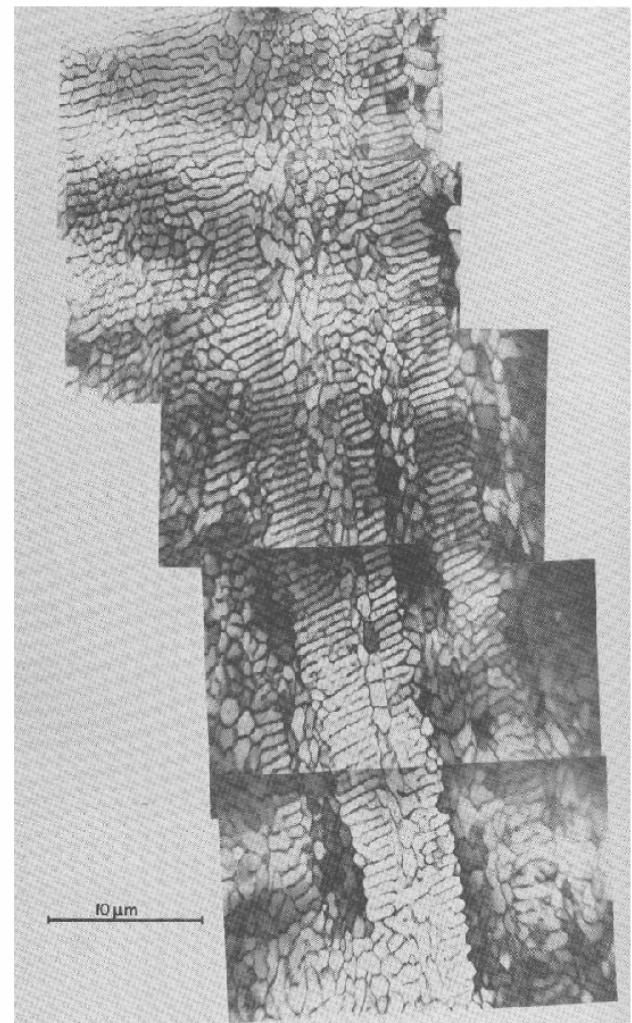
Subgrain dislocation structures - Fatigue

Dipolar dislocation walls

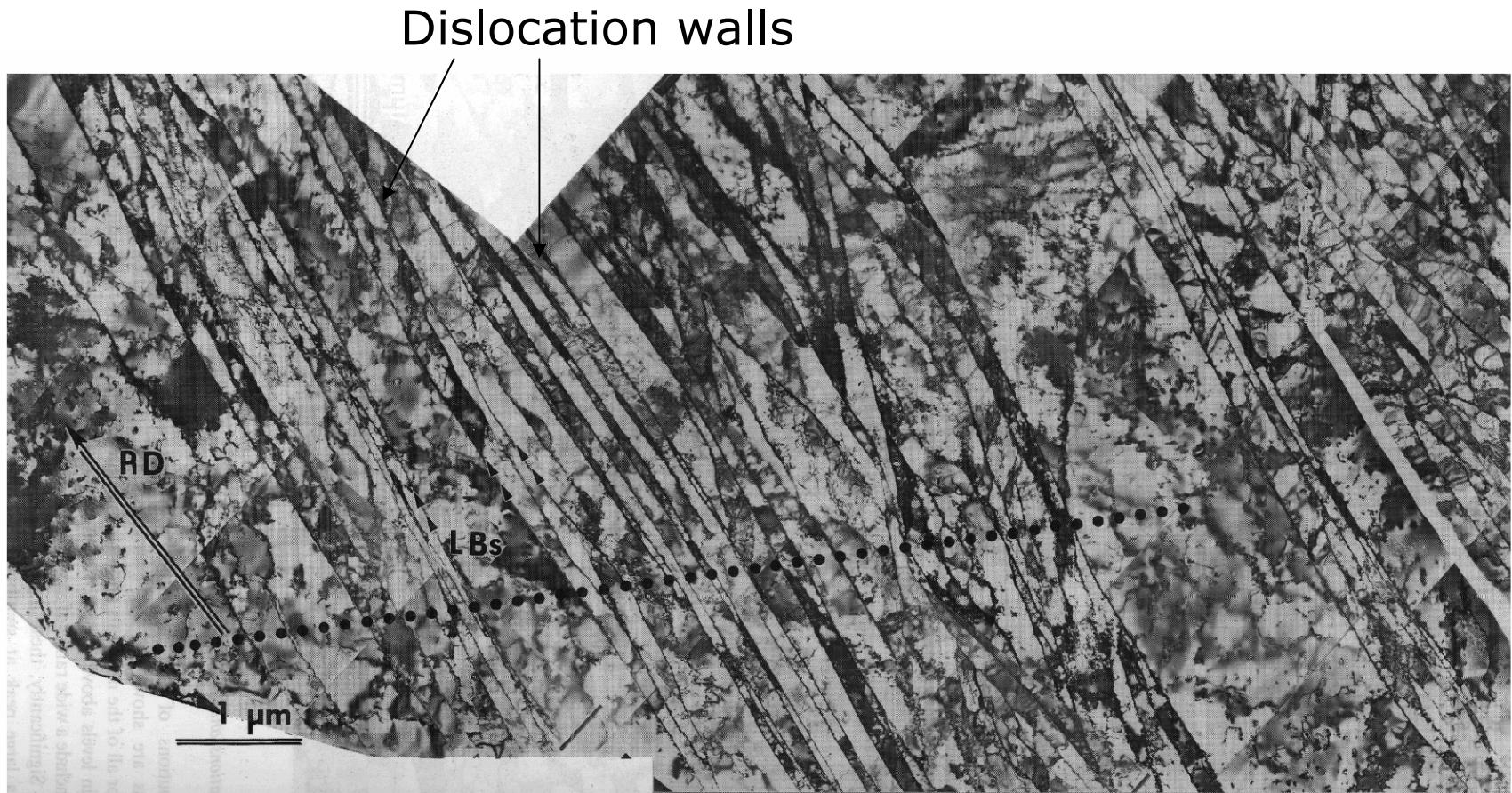


Labyrinth structure in fatigued
copper single crystal
(Jin and Winter, 1984)

Nested bands in copper single crystal
fatigued to saturation →
(Ramussen and Pedersen, 1980)



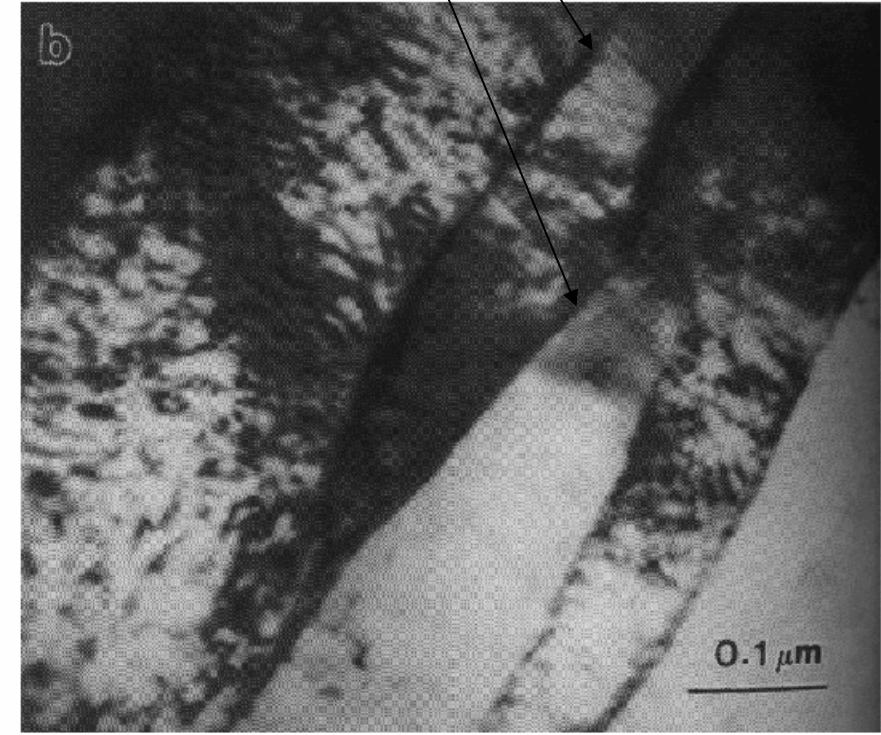
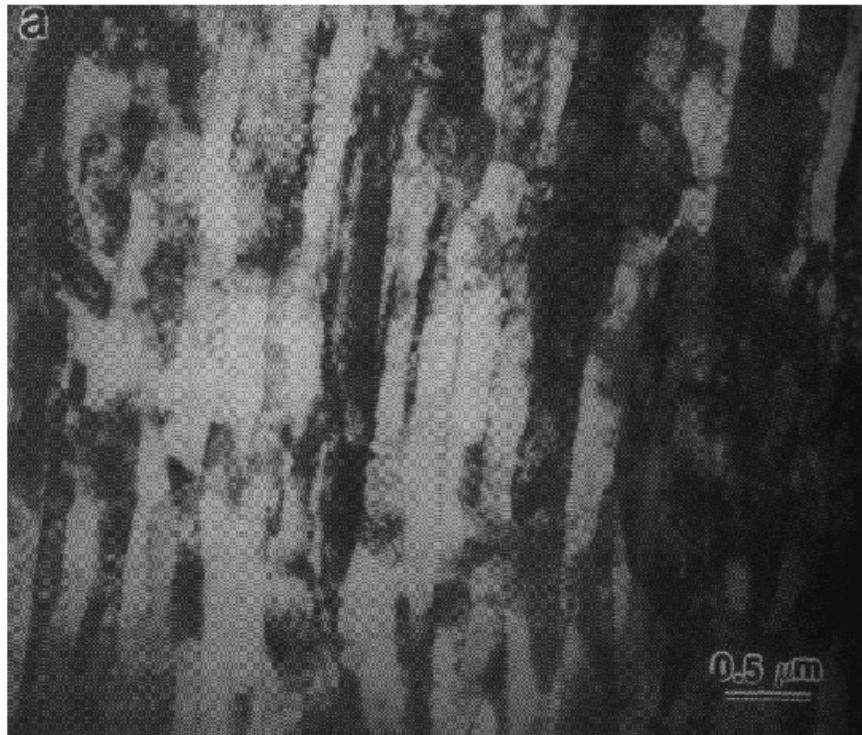
Subgrain dislocation structures - Static



90% cold rolled Ta (Hughes and Hansen, 1997)



Subgrain dislocation structures - Shock

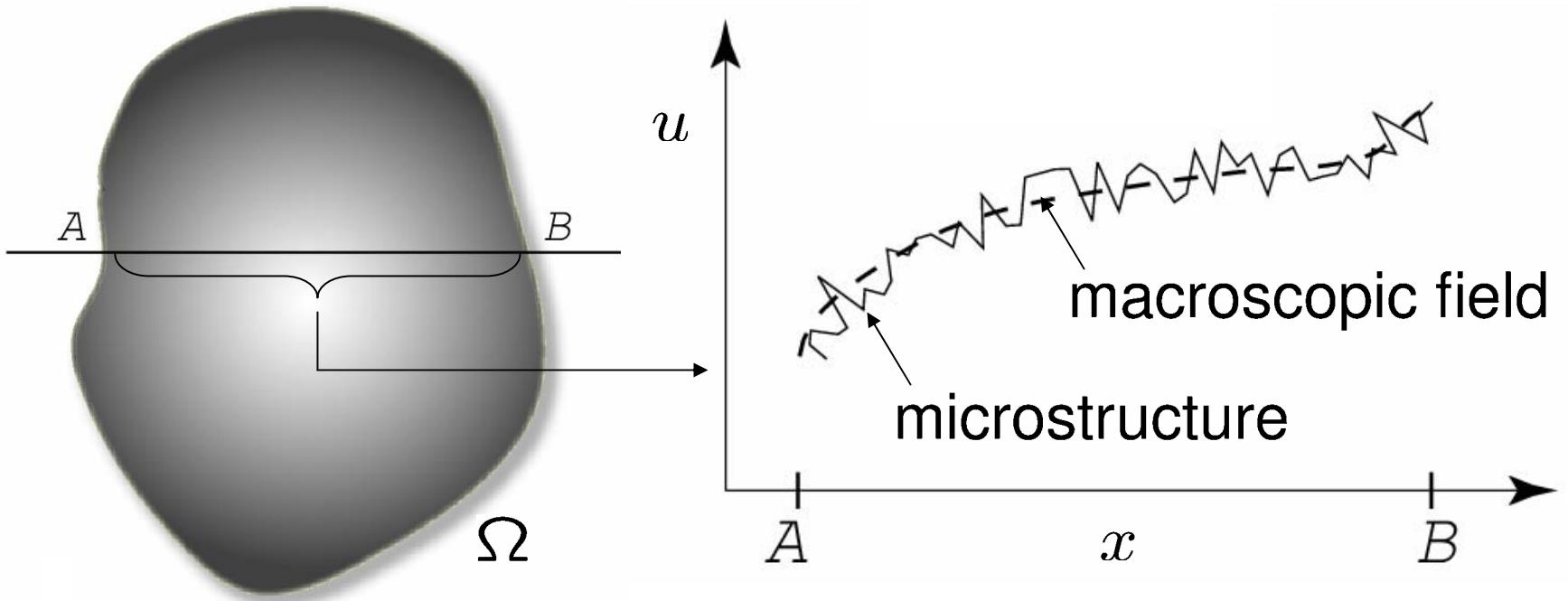


Dislocation walls

Shocked Ta (Meyers et al., 1995)



Relaxation



- Separation of scales, two coupled problems:
 - **Relaxed problem:** Well posed, determines macroscopic field, e.g., by finite-element analysis.
 - **Relaxation problem:** Determines microstructure, effective energetics, at the **subgrid** level



Relaxation

- Lower semicontinuous envelop:

$$sc^- F = \text{Largest lsc function } \leq F$$

- Relaxed problem: $m_X(F) = \inf_{u \in X} sc^- F(u)$

- Functions of integral form: $F(u) = \int_{\Omega} W(\nabla u) dx$

- Then: $sc^- F(u) = \int_{\Omega} QW(\nabla u) dx$, where

$$QW(A) = \inf_{v \in W_0^{1,\infty}(E)} \frac{1}{|E|} \int_E W(A + \nabla v) dx$$

is the *quasiconvex* envelop of W .



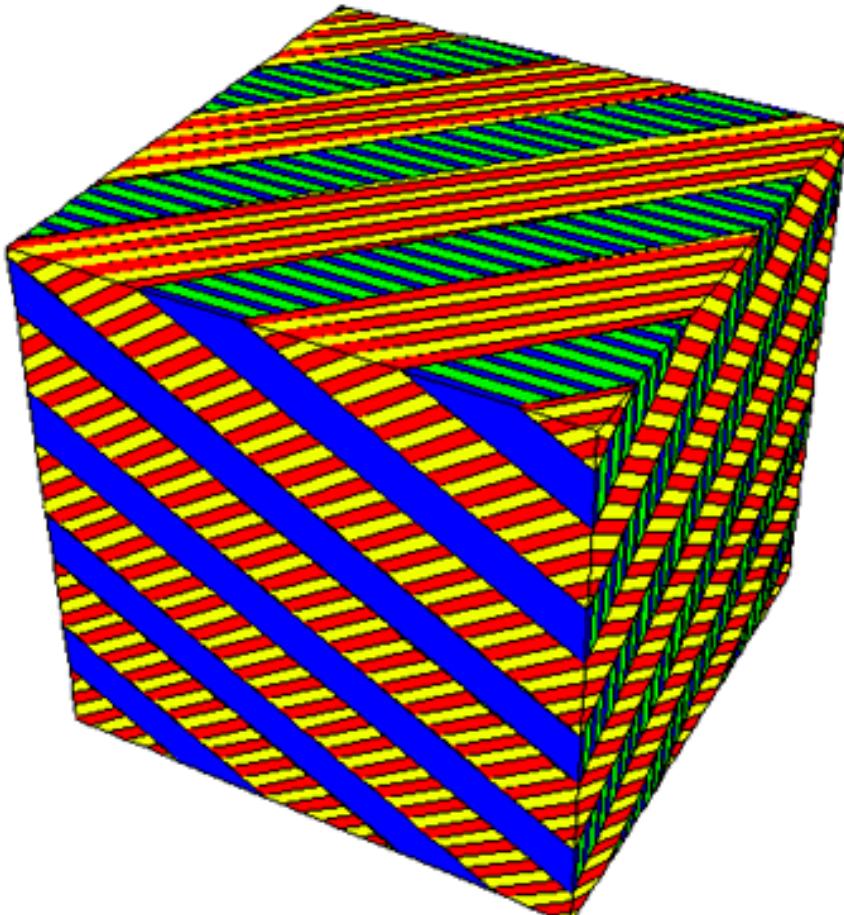
Relaxation

Theorem. Let $F : X \rightarrow \bar{\mathbb{R}}$ be coercive. Then:

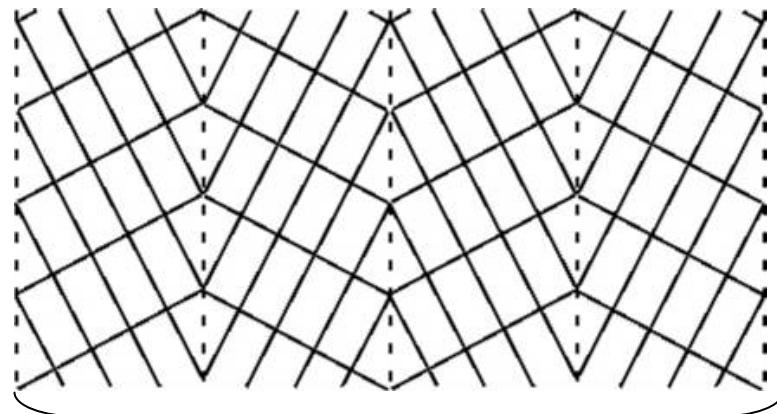
- (i) sc^-F is coercive and lower semicontinuous.
- (ii) sc^-F has a minimum point in X .
- (iii) $\min_{u \in X} sc^-F(u) = \inf_{u \in X} F(u)$.
- (iv) Every cluster point of a minimizing sequence of F is a minimum point of sc^-F in X .
- (v) If, in addition, X is first-countable, then every minimum point of sc^-F is the limit of a minimizing sequence of I in X .



Relaxation – Sequential lamination



Rank-2 laminate

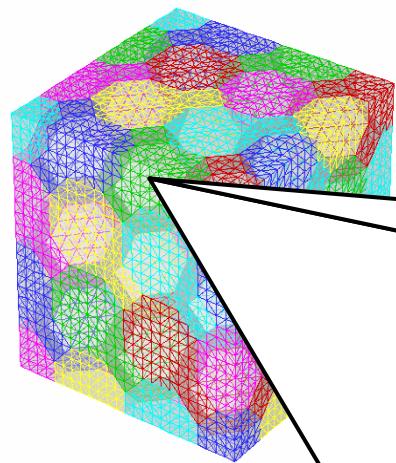


Coherent interfaces

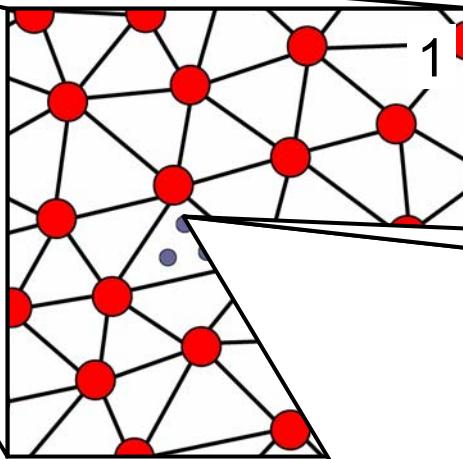
- Compatibility.
- Equilibrium.
- Optimize:
 - i) Orientations.
 - ii) Volume fractions.



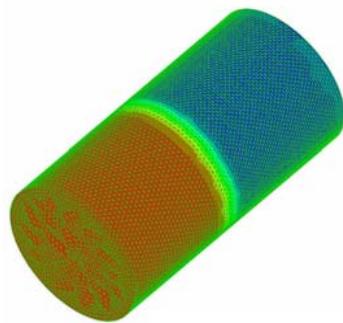
Relaxation – Concurrent multiscale



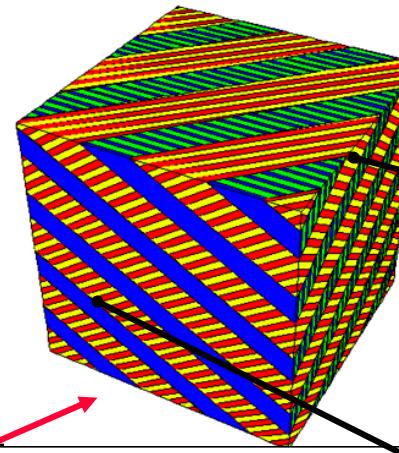
Microstructures generated
at quadrature points on the fly



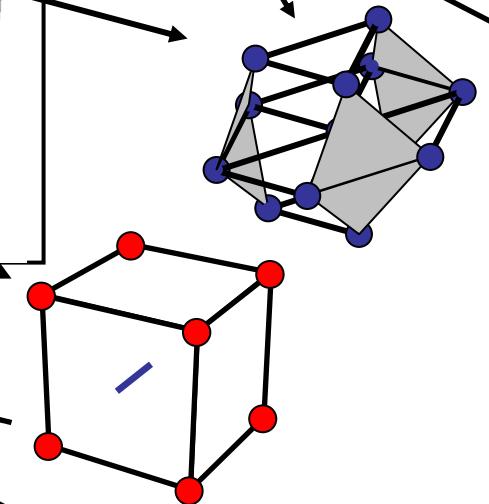
average
deformation



average
stress



local
deformation

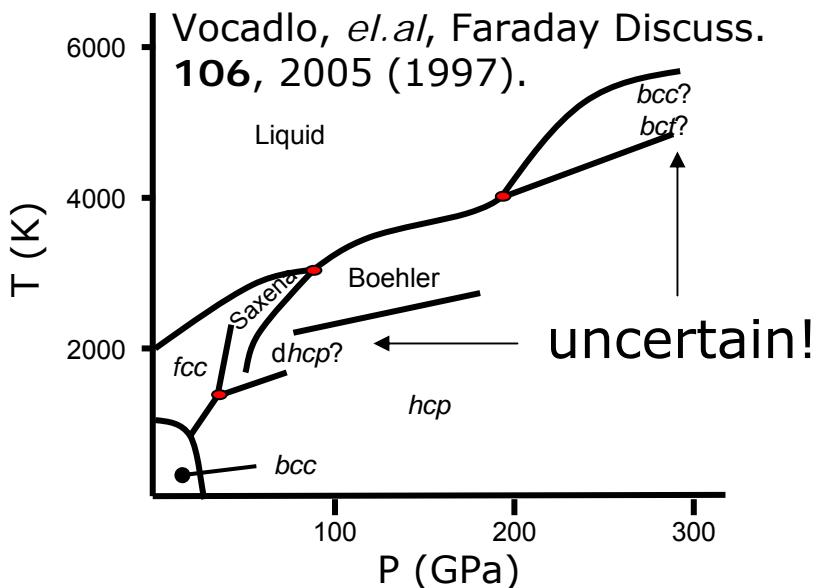


local
stress

Sequential lamination
(Aubry et al. '03)



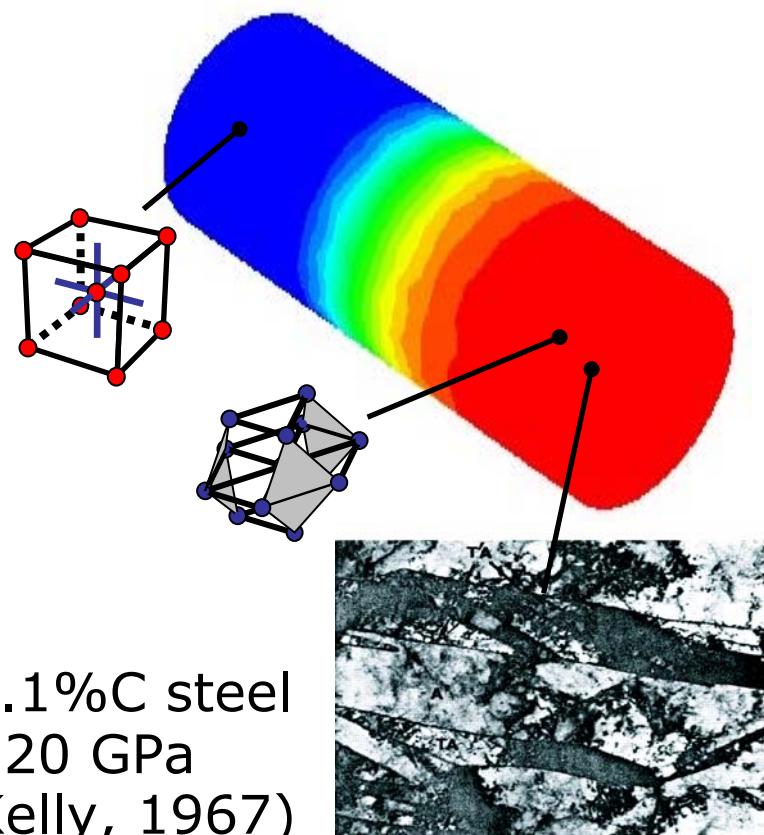
Phase transitions in Fe



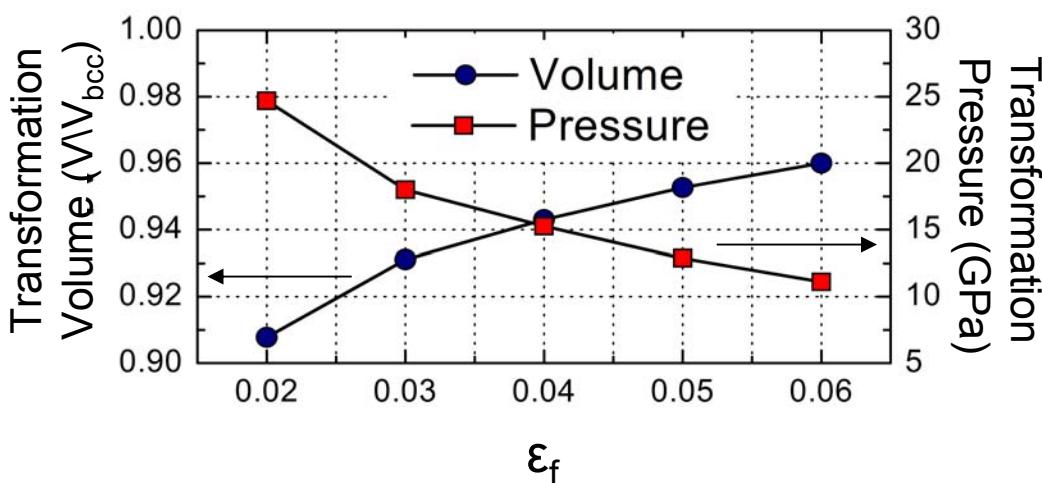
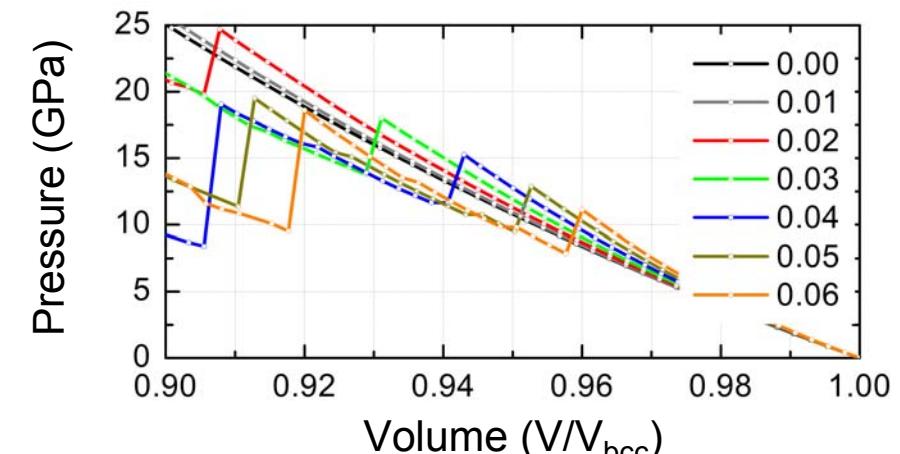
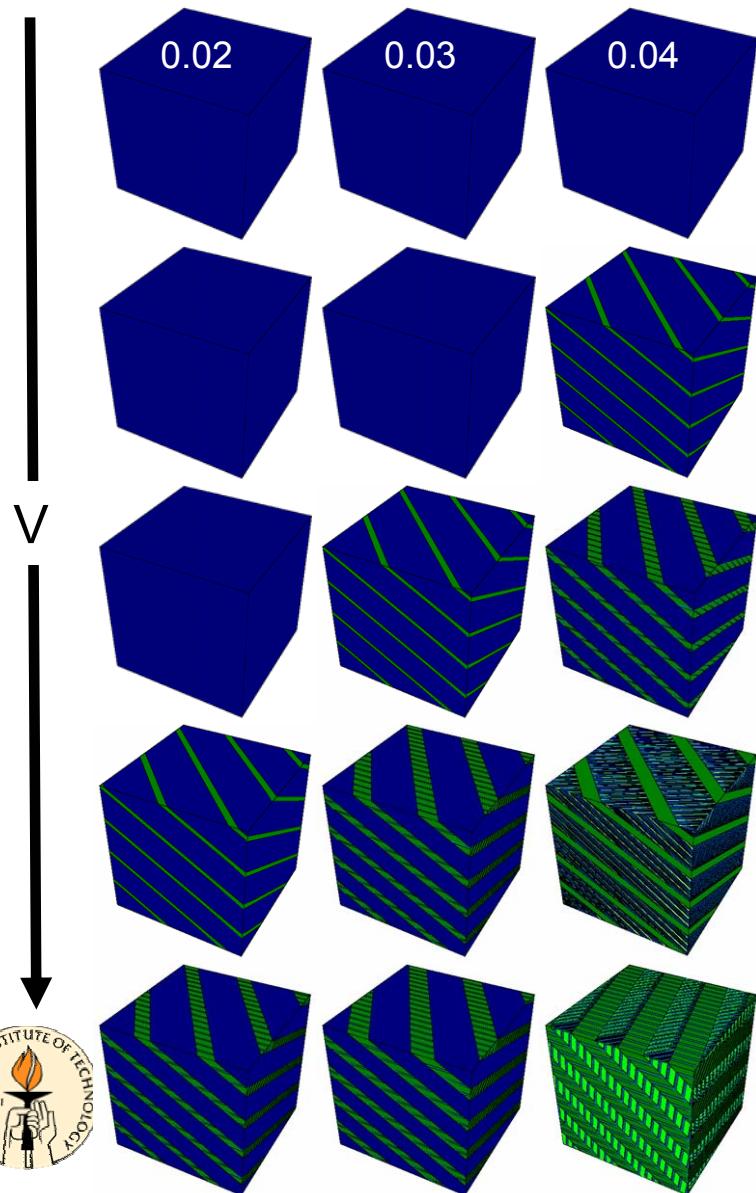
Ground state ferromagnetic *bcc* undergoes a *martensitic* phase transformation to non-magnetic *hcp* at ~ 10 GPa.

ϵ platelets in 0.1%C steel shocked to 20 GPa
(Bowden and Kelly, 1967)

Strong shocks induce phase transitions involving complex microstructures



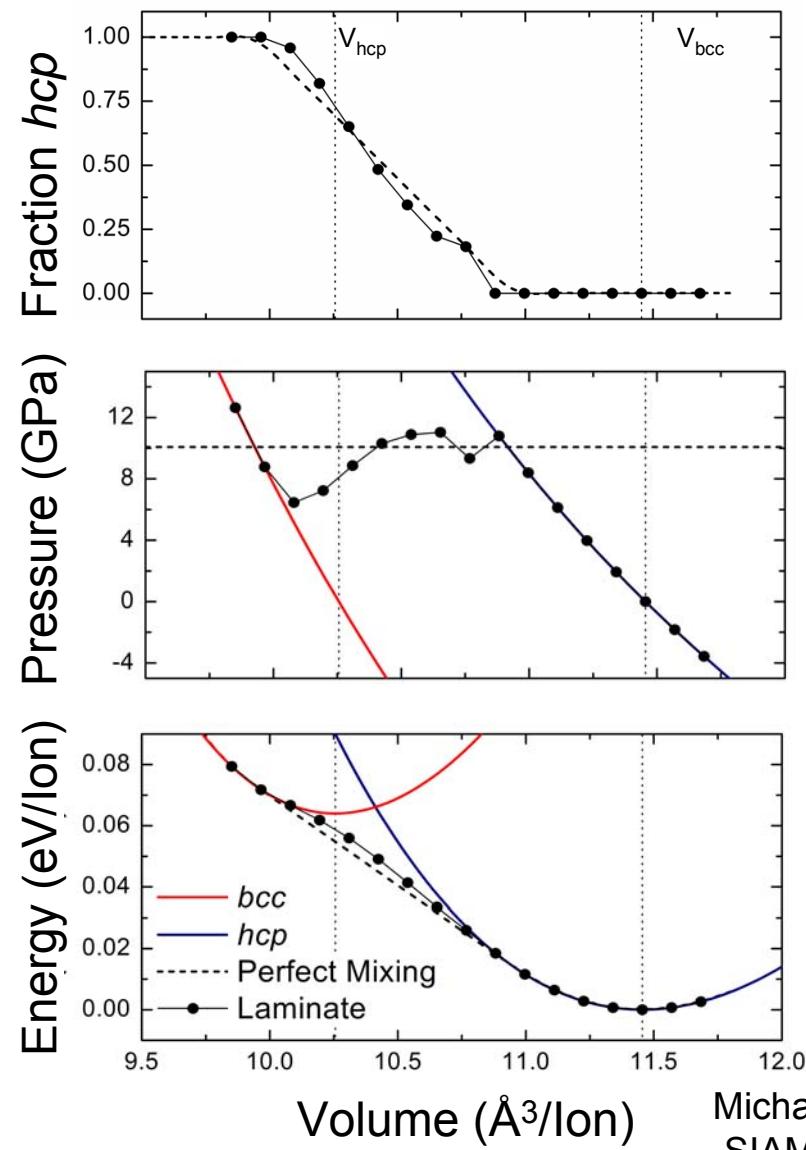
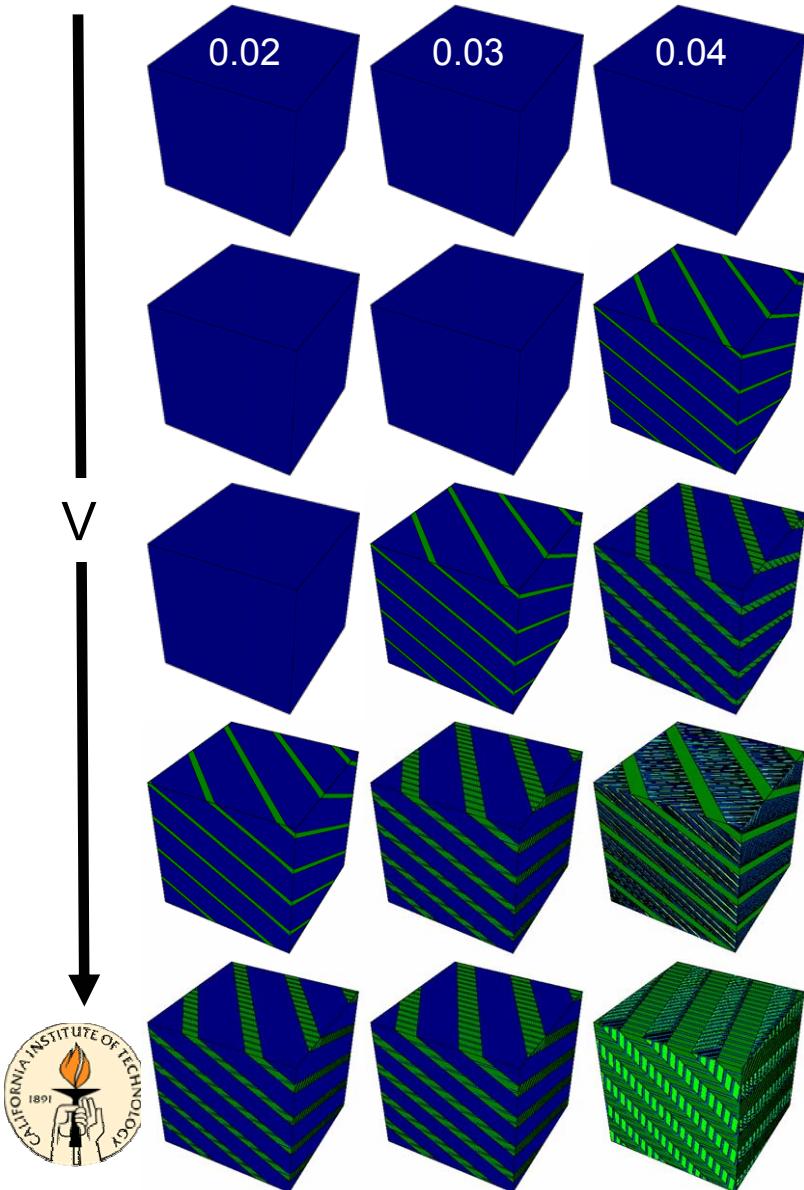
Phase transitions in Fe



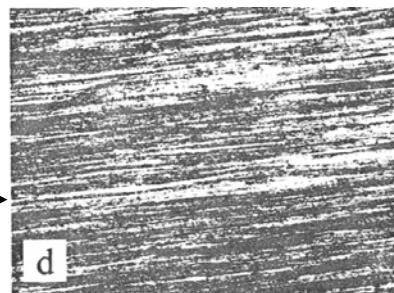
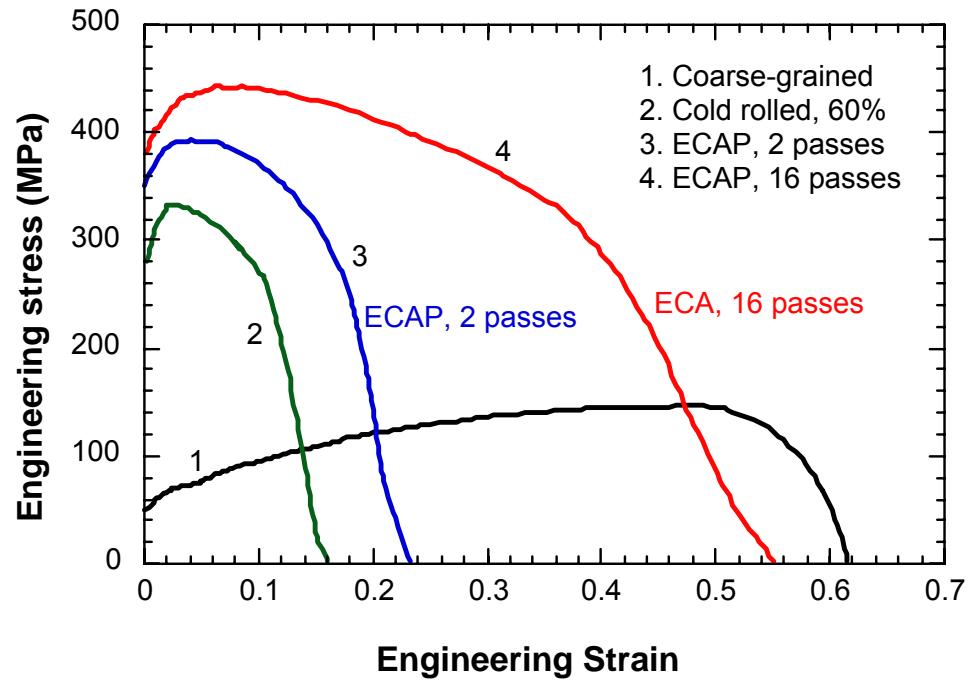
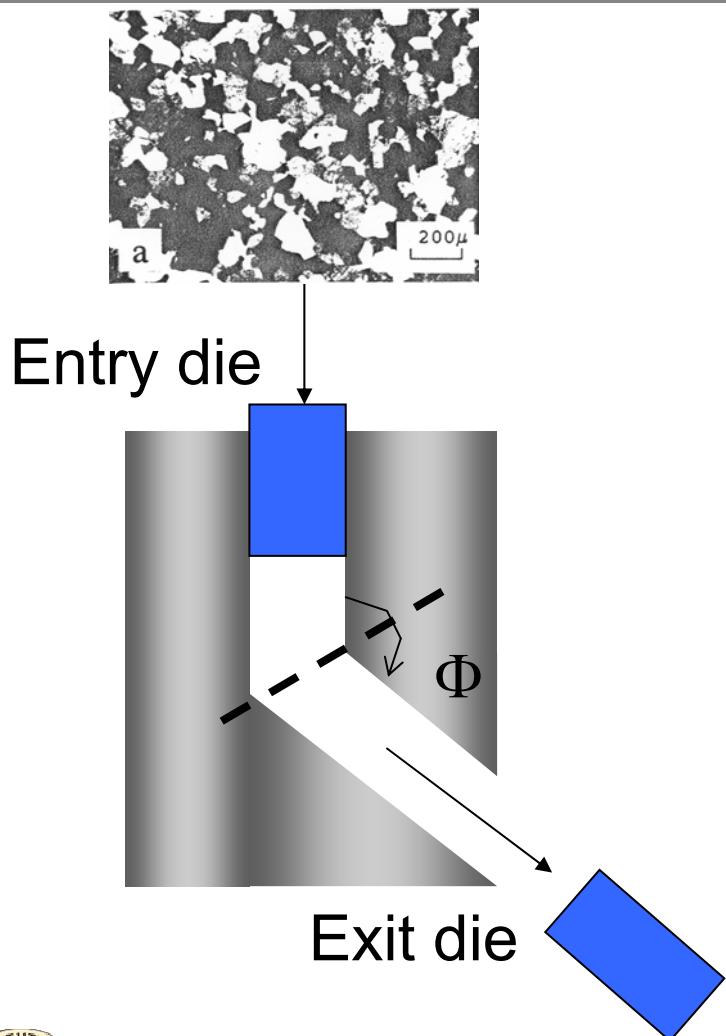
(K.J. Caspersen *et al.* PRL '04)



Phase transitions in Fe



Equal Angular Channel Extrusion



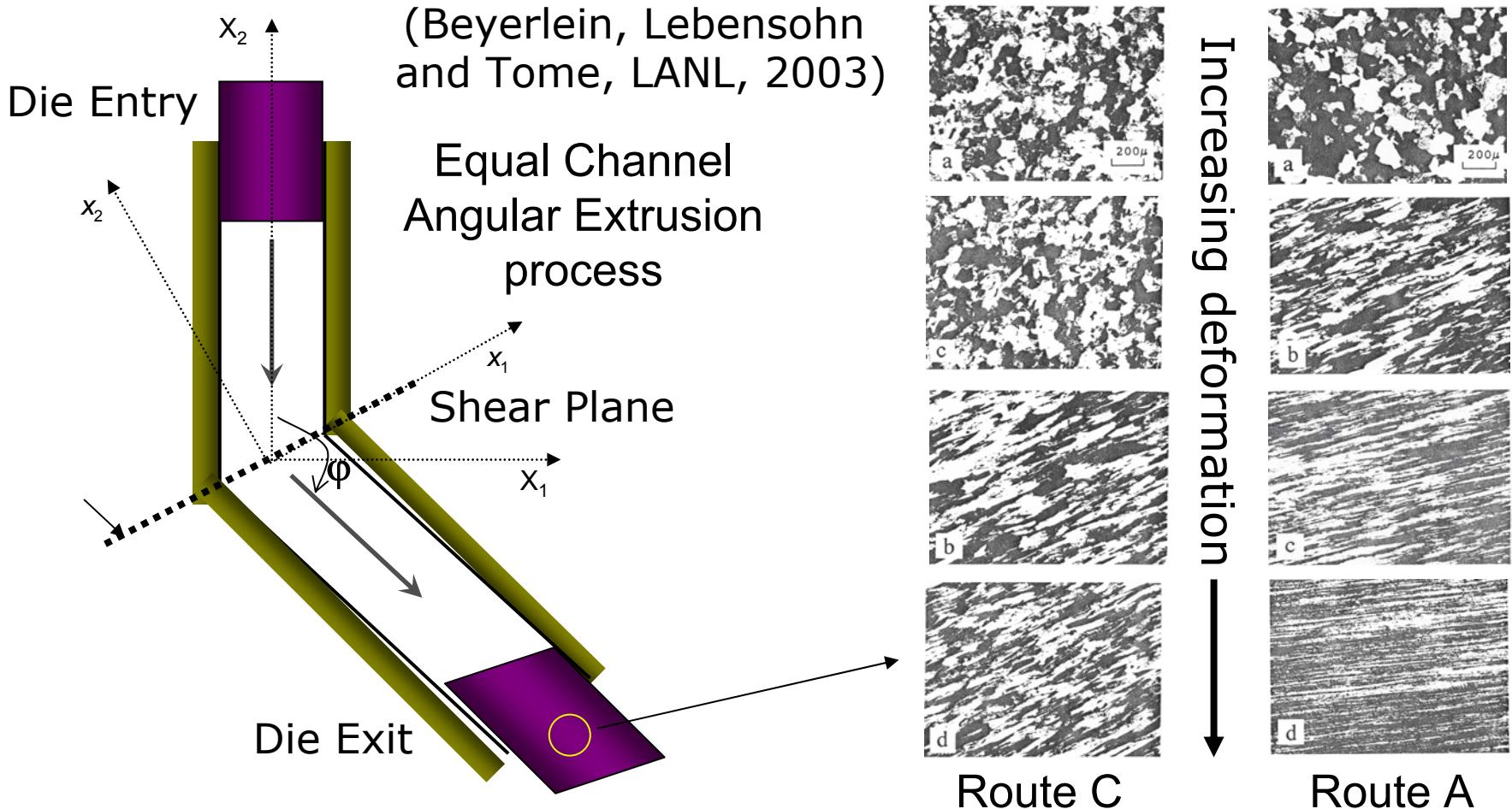
Nanoscale
polycrystal

(Beyerlein, Lebensohn and Tome, LANL, 2003)

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SIAM 02/05

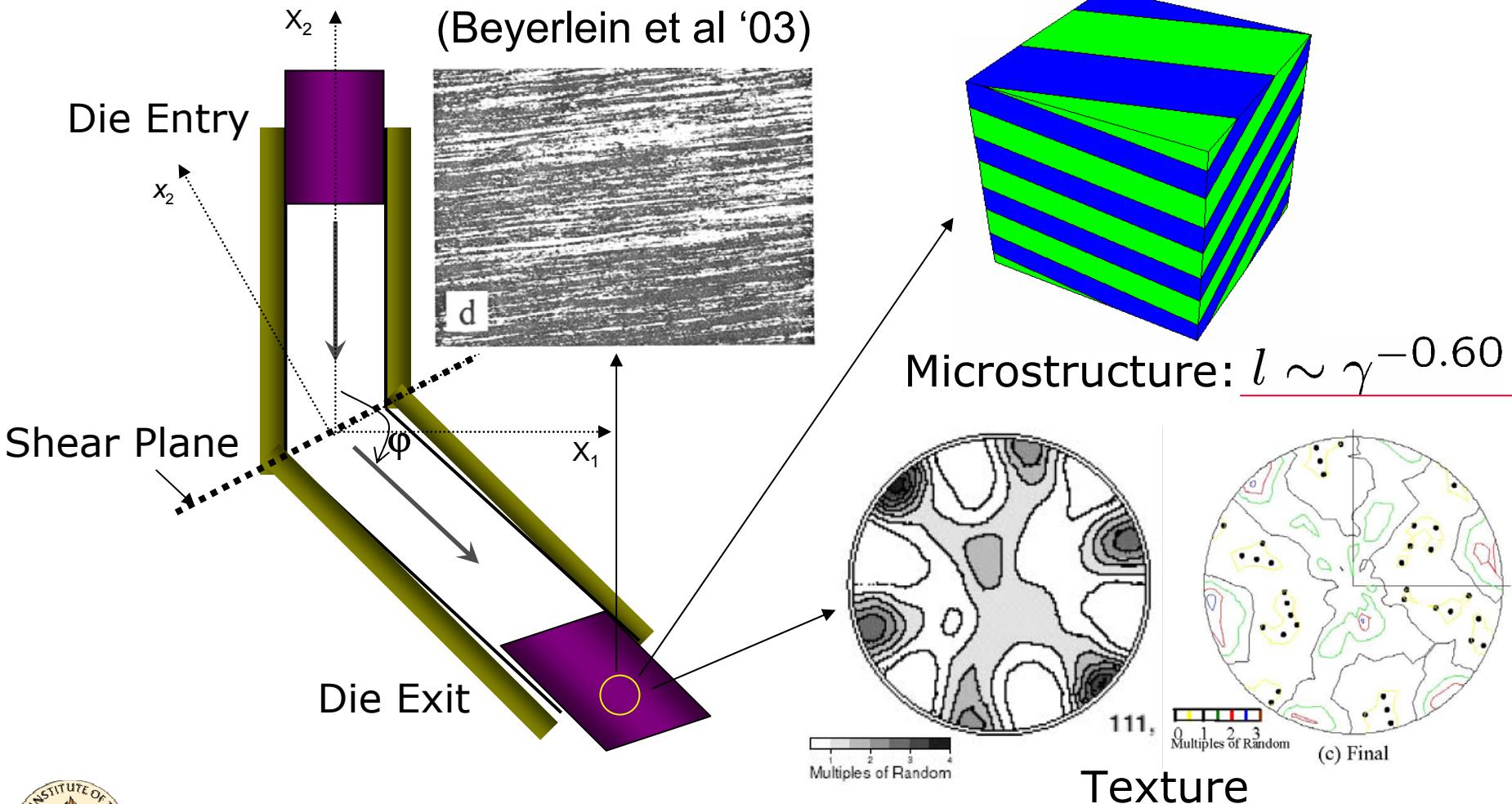


Equal Angular Channel Extrusion



Evolution of dislocation structures in Cu specimen. Lamellar width: $l \sim \gamma^{-0.65}$

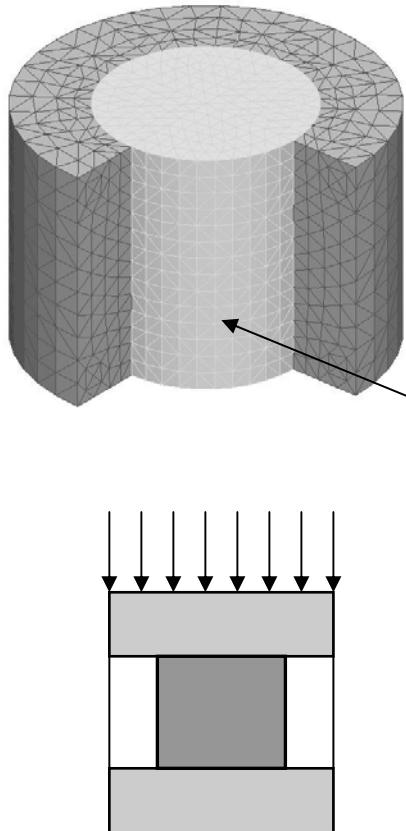
Equal Angular Channel Extrusion



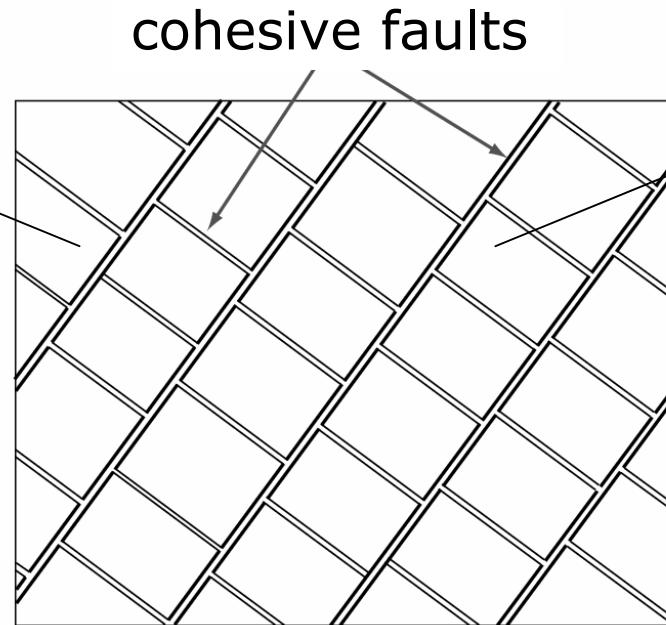
(Sivakumar and Ortiz '03)

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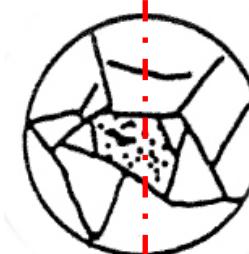
Distributed brittle damage



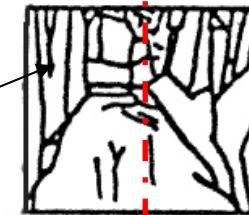
Sintered aluminum nitride (AlN)
Confined with a brass sleeve
(Chen and Ravichandran '96)



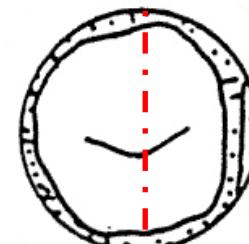
Sequential faulting construction
(Pandolfi, Conti and Ortiz '05)



Top view



Cross Section



Bottom view

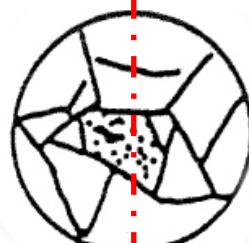
Damage distribution



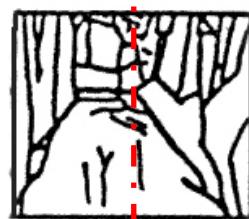
Distributed brittle damage

Experiments
(Chen and
Ravichandran '96)

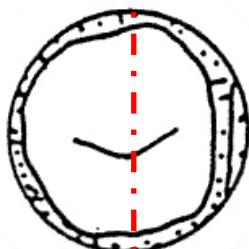
Top view



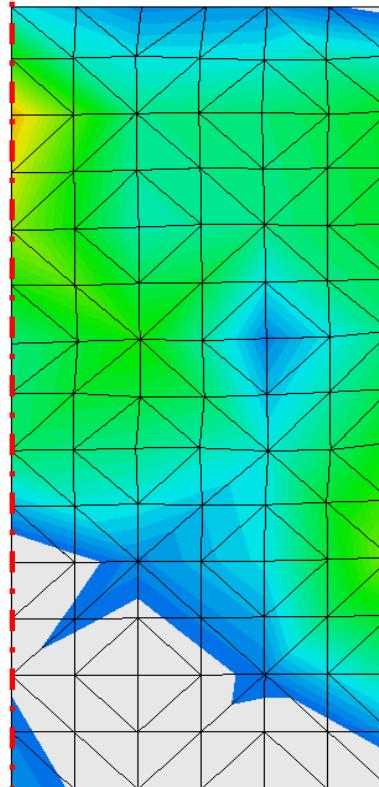
Cross Section



Bottom view

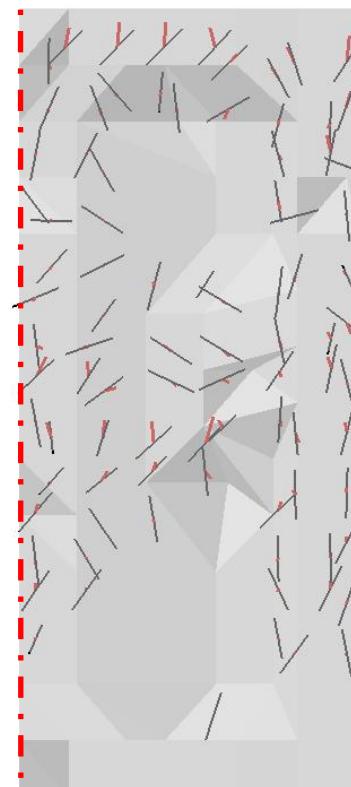


Damage
contour levels
Cross section

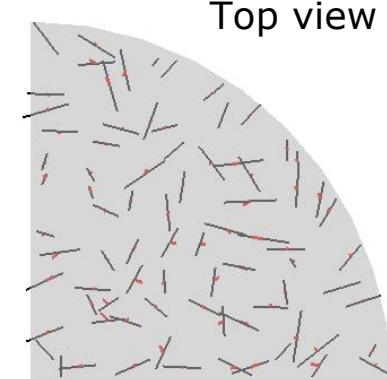


Fault planes (black) and opening (red)

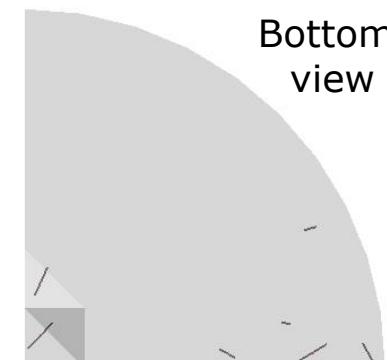
Cross section



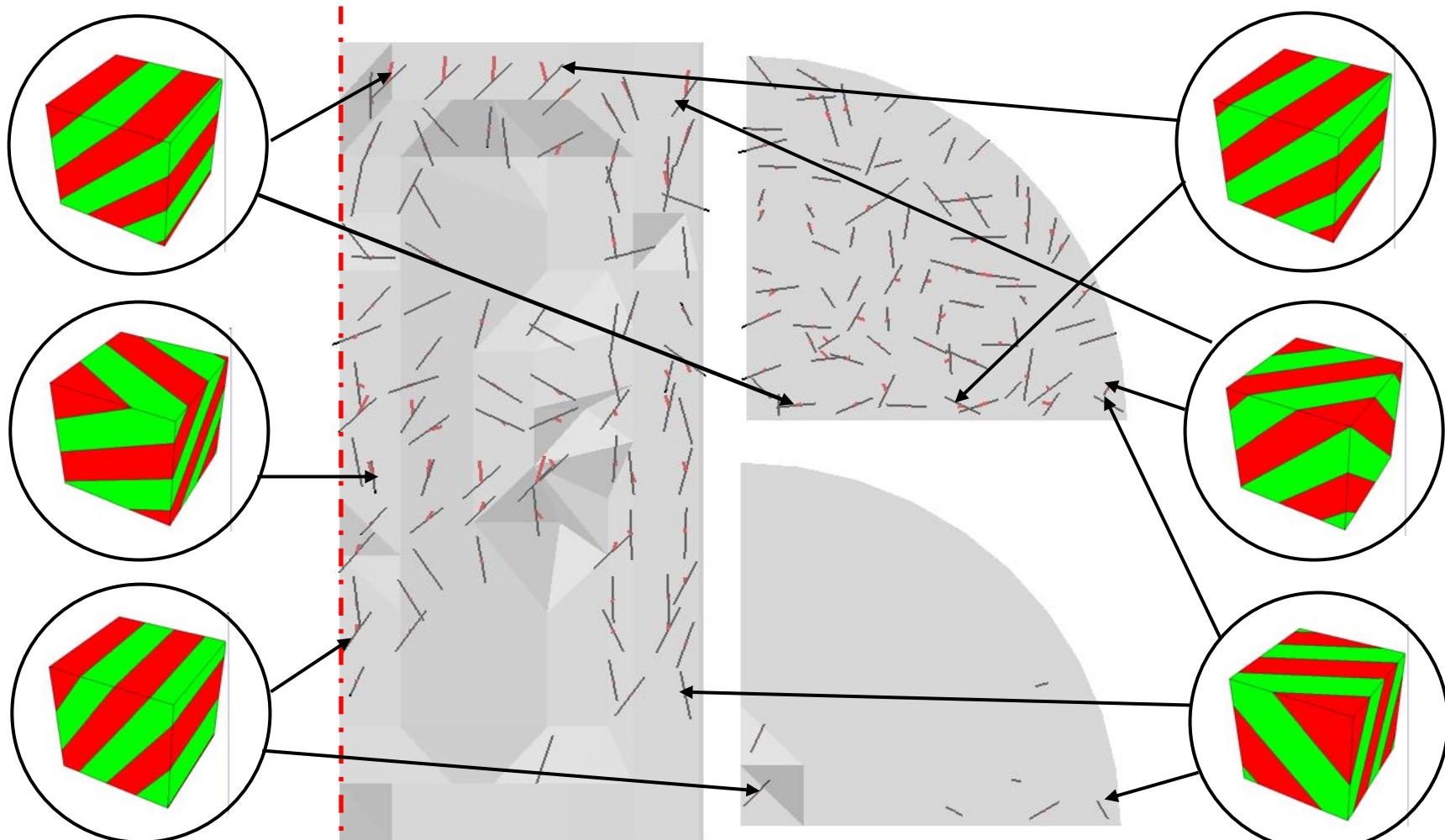
Top view



Bottom view



Distributed brittle damage

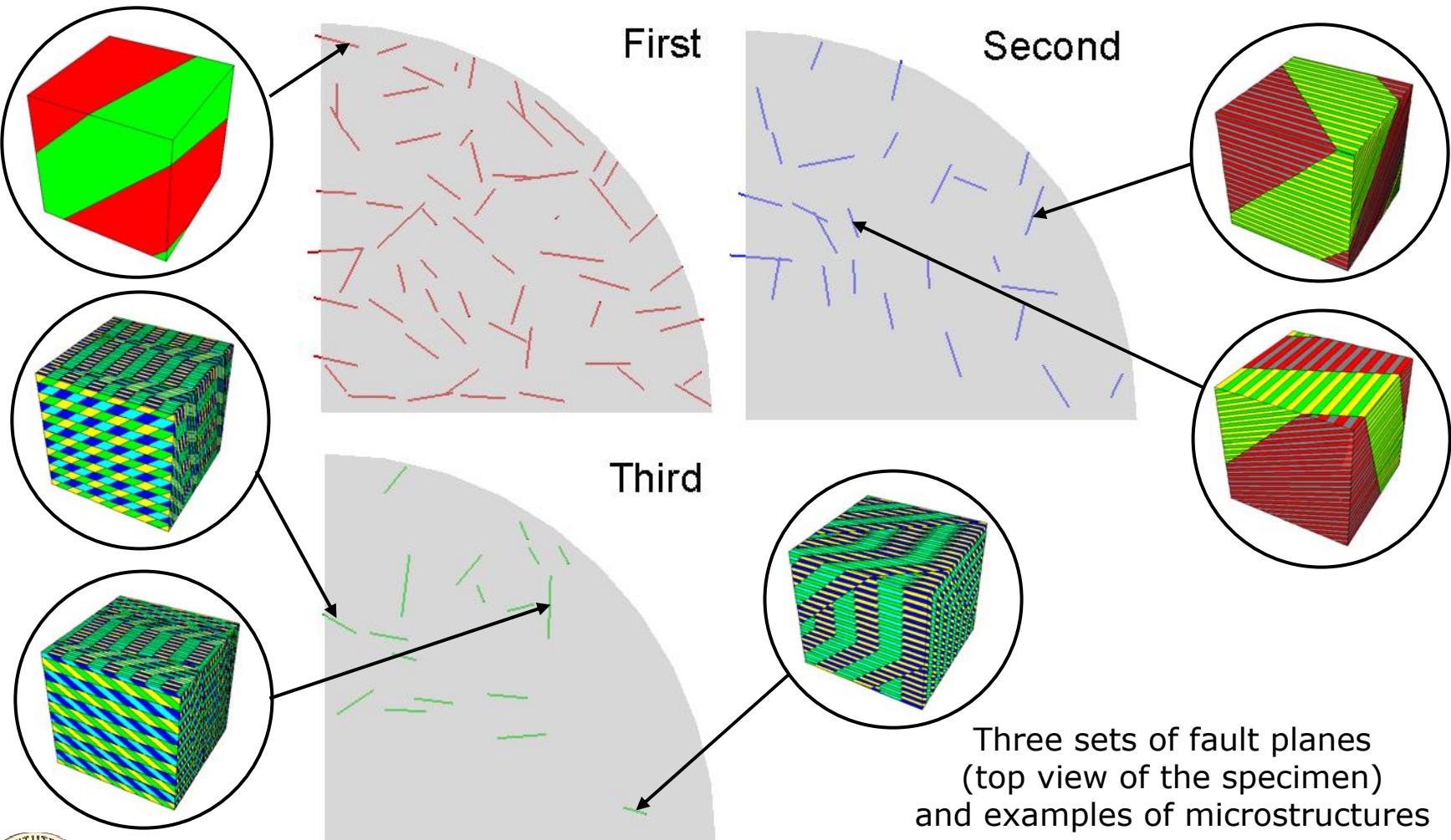


Normals (black) and opening displacement (red)

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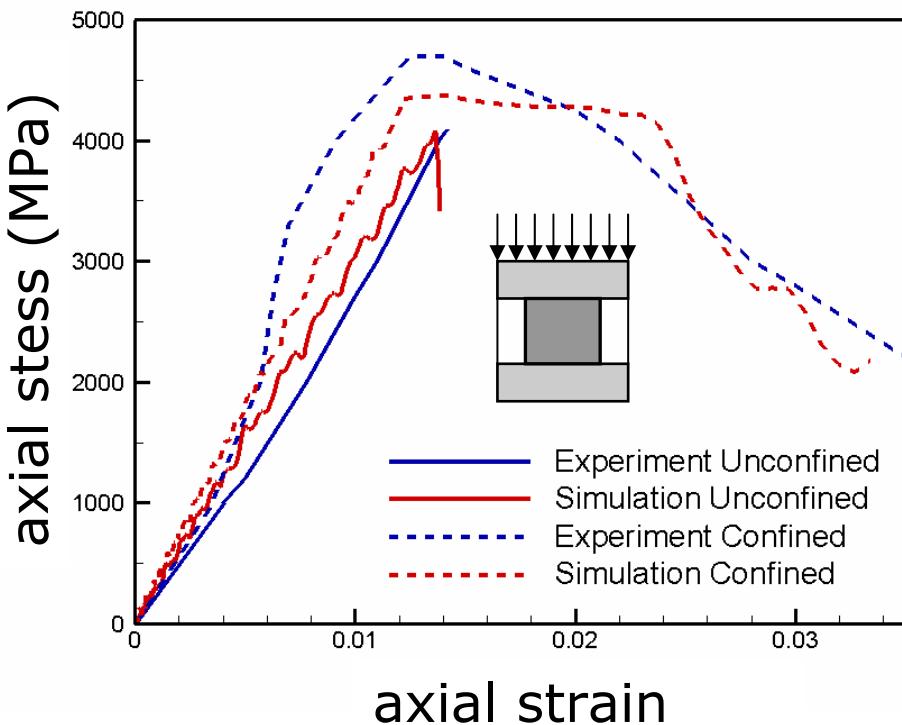


Distributed brittle damage

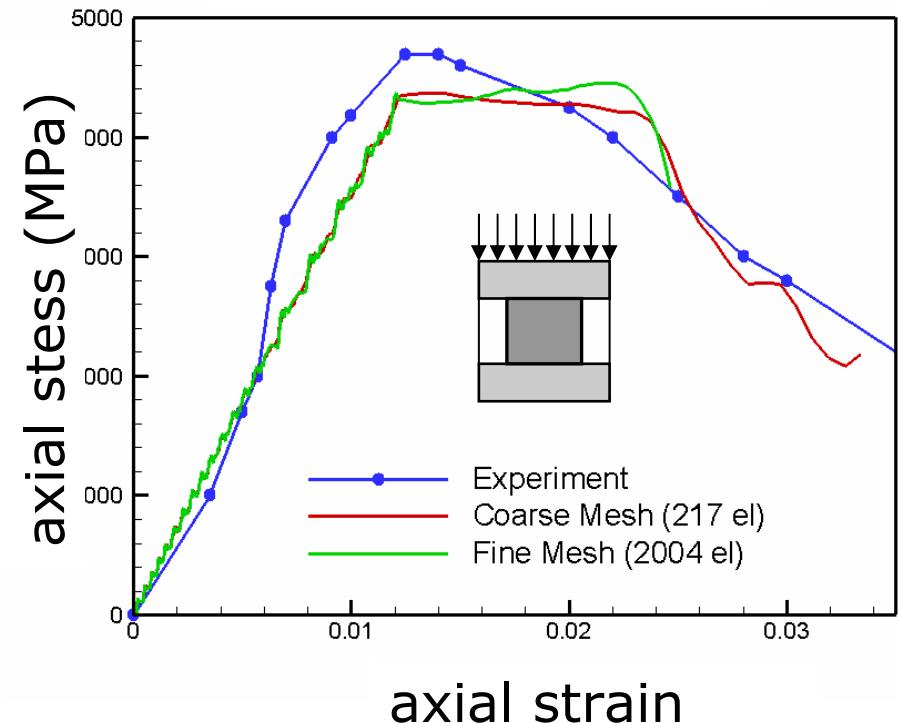


Distributed brittle damage

Comparison with experiment



Mesh size analysis



Validation and verification of sequential faulting construction



Relaxation – Outlook

- Relaxation is an example of a top-down multiscale method that relies on:
 - *Strict separation of scales*
 - *Well-posed macroscopic problem*
 - *Sub-grid evaluation of microstructure*
- Relaxation is an example of a *concurrent multiscale computing*: it resolves macroscopic and microscopic lengthscales concurrently during same calculation
- Challenges:
 - *Nonlocal effects* (eg, *interfacial energy*), *size effects*
 - *Kinetics* (eg, *interfacial motion*, *pinning*)
 - *Relaxation beyond sequential lamination*

Conclusion

- “In anticipation of ASC Purple in 2005, we are shifting our emphasis from developing parallel-architecture machines and codes to improved weapons science and increased physics understanding of nuclear weapons.” (**Randy Christensen**).
- “The computers come, and after a few years, they go, But the codes and code teams endure.” (**Mike McCoy**).
- “The credibility of our simulation capabilities is central to the credibility of the certification of the nuclear stockpile. That credibility is established through V&V analyses.” (**Cynthia Nitta**).

